

New Dimensions in Performance

Harnessing 3D Integration Technologies

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Yorktown Heights, NY**

9 September, 2008

Fort Collins, CO

“Escher Envy” courtesy of David Bryant

3D Press Release

Wall Street Journal: IBM Touts Breakthrough in 3-D Chips

By WILLIAM M. BULKELEY

April 12, 2007; Page B3

International Business Machines Corp. said it achieved a breakthrough in developing a three-dimensional semiconductor chip that can be stacked on top of another electronic device in a vertical configuration long sought by engineers to reduce size and power use.

Agenda

- 1) Workloads**
- 2) The Memory Wall, Bandwidth, and Latency**
- 3) The Technologies of 3D Integration**
- 4) “The future ain’t what it used to be.”**
- 5) Summary**
- 6) Human Scaling**

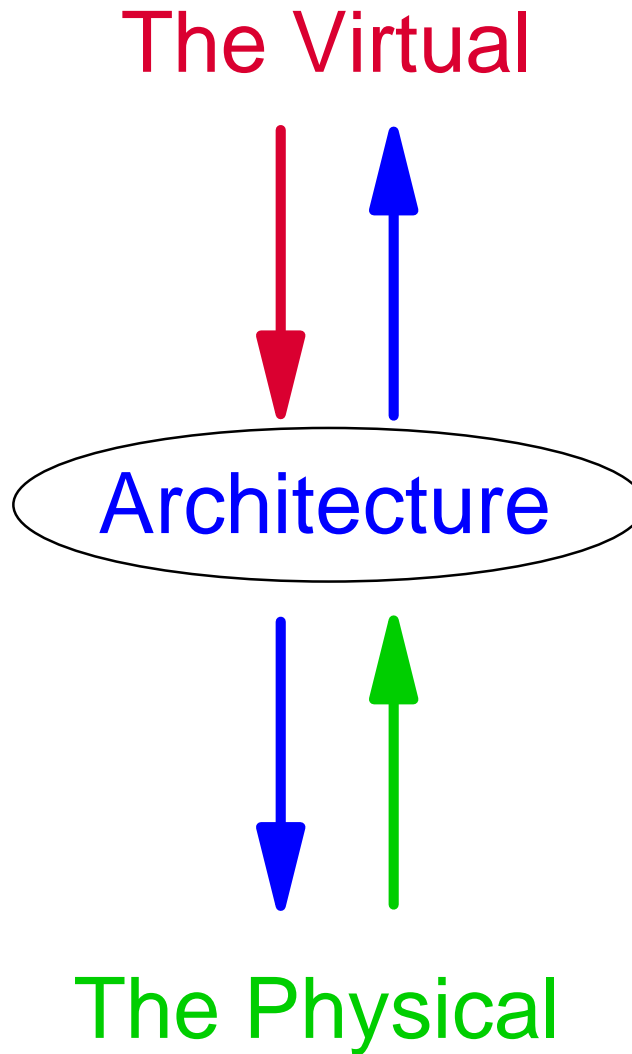
Computer Workloads & Thru-put

Workloads – What do Computers do?

- **Scientific (i.e. Lawrence Livermore National Labs)**
 - Highly regular, predictable patterns allows streaming data from cache to processor
 - Performance is directly proportional to bus bandwidth
 - High utilization, full data bus at all times
- **Commercial (i.e. Starbucks)**
 - Unpredictable irregular patterns
 - Miss rate follows Poisson process (random)
 - Requires low bus utilization to avoid clogs in the event of a burst of misses (usually 30% bus utilization)
- **Both application spaces need BW, but for different reasons**

The Software Stack:

- System
 - Hypervisor
 - Operating System
- Applications Layer
- Program
- Compiler
- Machine Language



Architecture:

A fully-specified
unambiguous
contract

The Hardware Stack:

- Logical Level Description
- Machine Organization
- Schematic Representation
- Circuit Design
- Physical Design
- Device Level (transistors)
- Atomic Level

Processor Cores and Memory Subsystems

The New Units of Design

(Systems/Thread) x (Threads/Core) x (Cores / Die)

Puts pressure on Memory
Subsystem, Communication



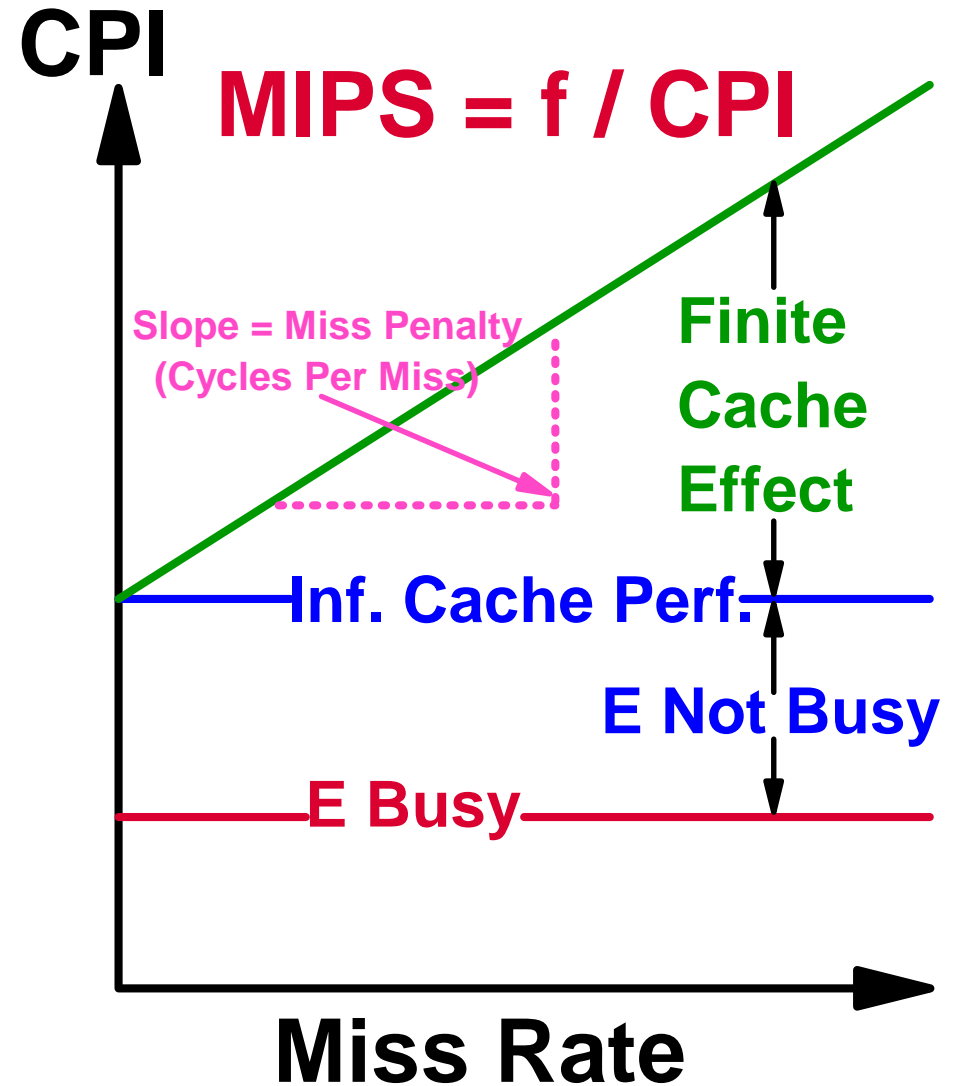
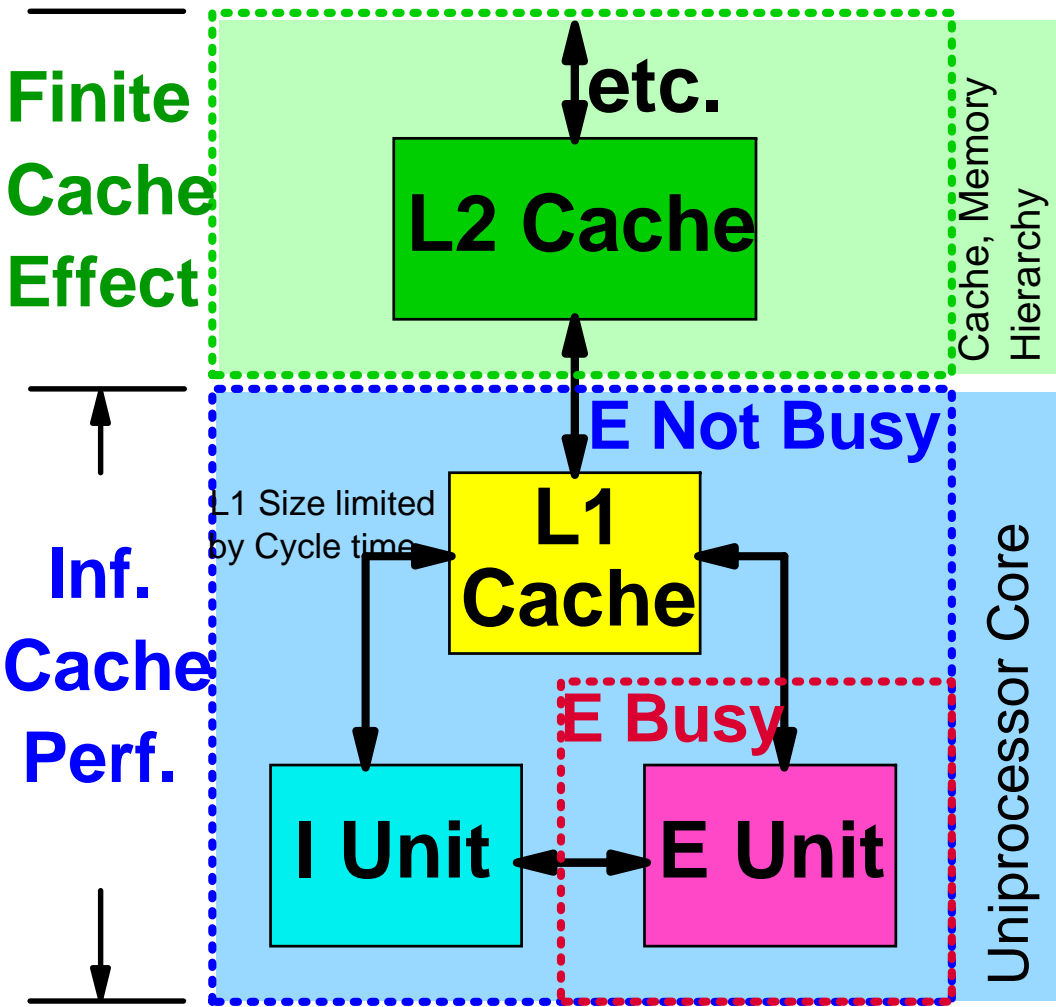
**On-chip content
(cache capacity)**

Inter, Intra-chip BW

Integration Focus moves from the device and circuit to core

Components of Processor Performance

From ISCA '06
Keynote address by
Phil Emma, IBM

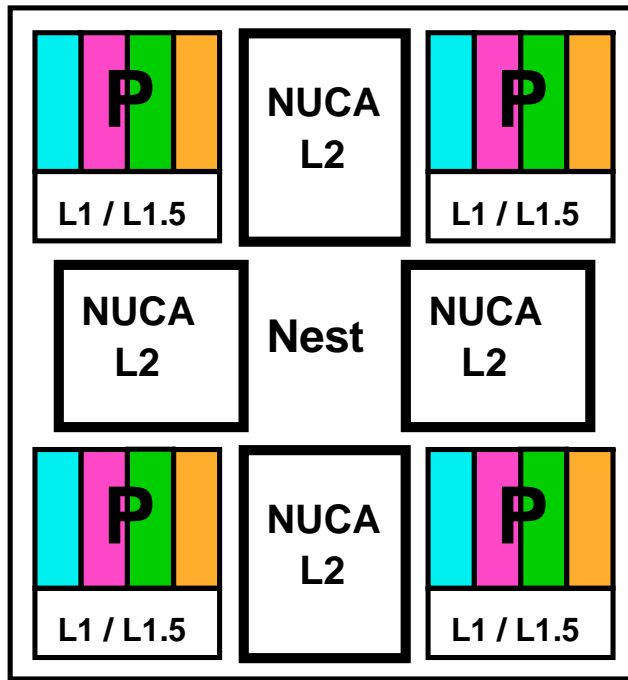


Delay is sequentially determined by a) ideal processor, b) access to local cache, and c) refill of cache

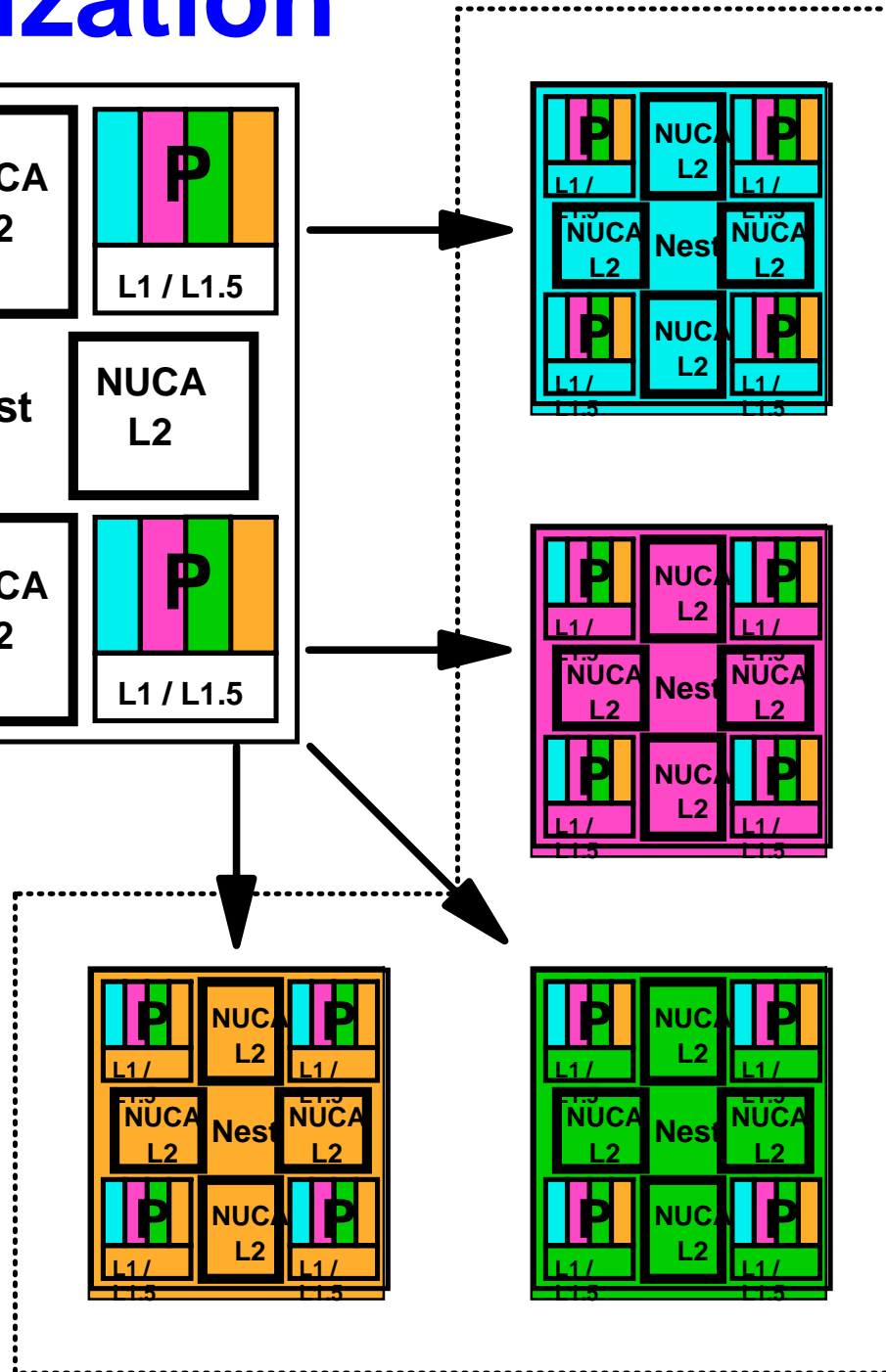
Virtualization

From ISCA '06
Keynote address by
Phil Emma, IBM

Real
System



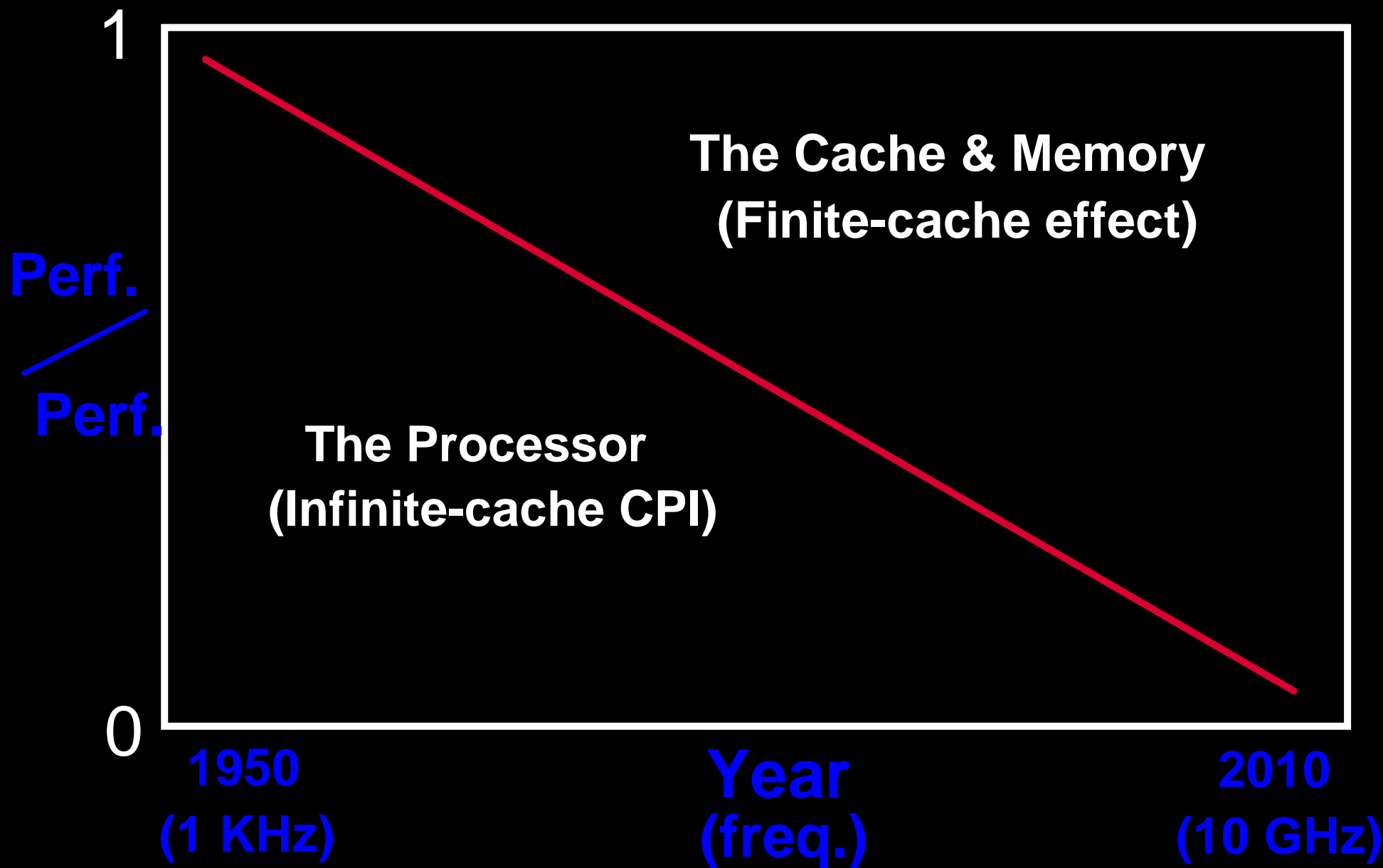
Independent
Virtual
Systems



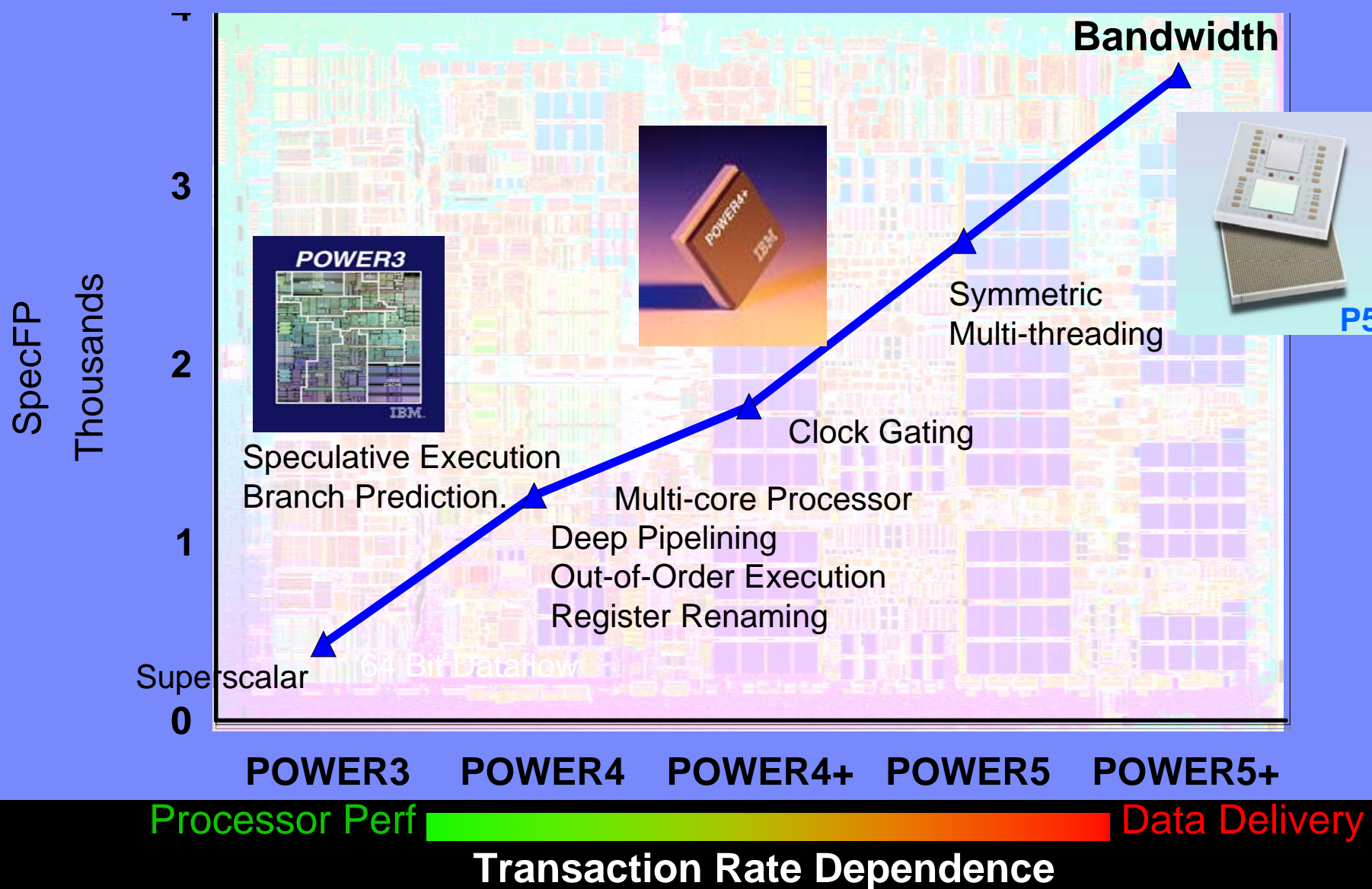
"Looks like"
4 independent
systems, each
with 16 cores!

What Dominates System Performance?

From ISCA '06
Keynote address by
Phil Emma, IBM

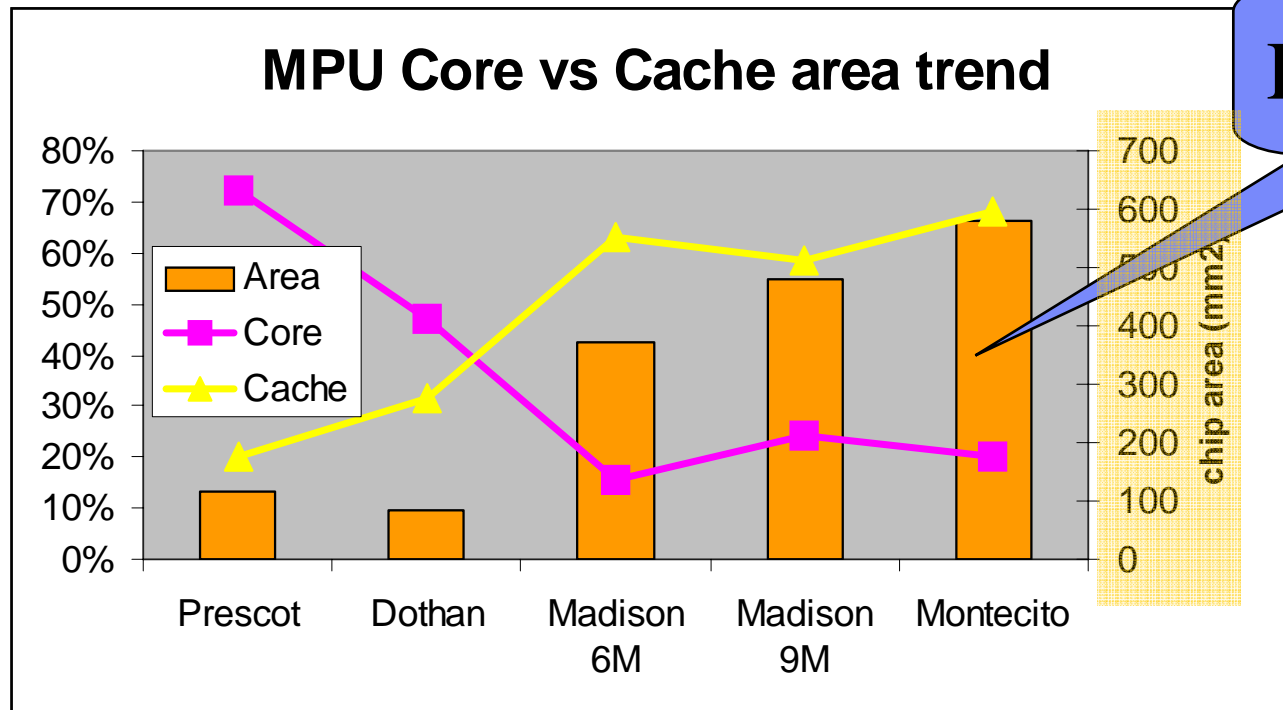


POWER Series Architectural Perf Contributions



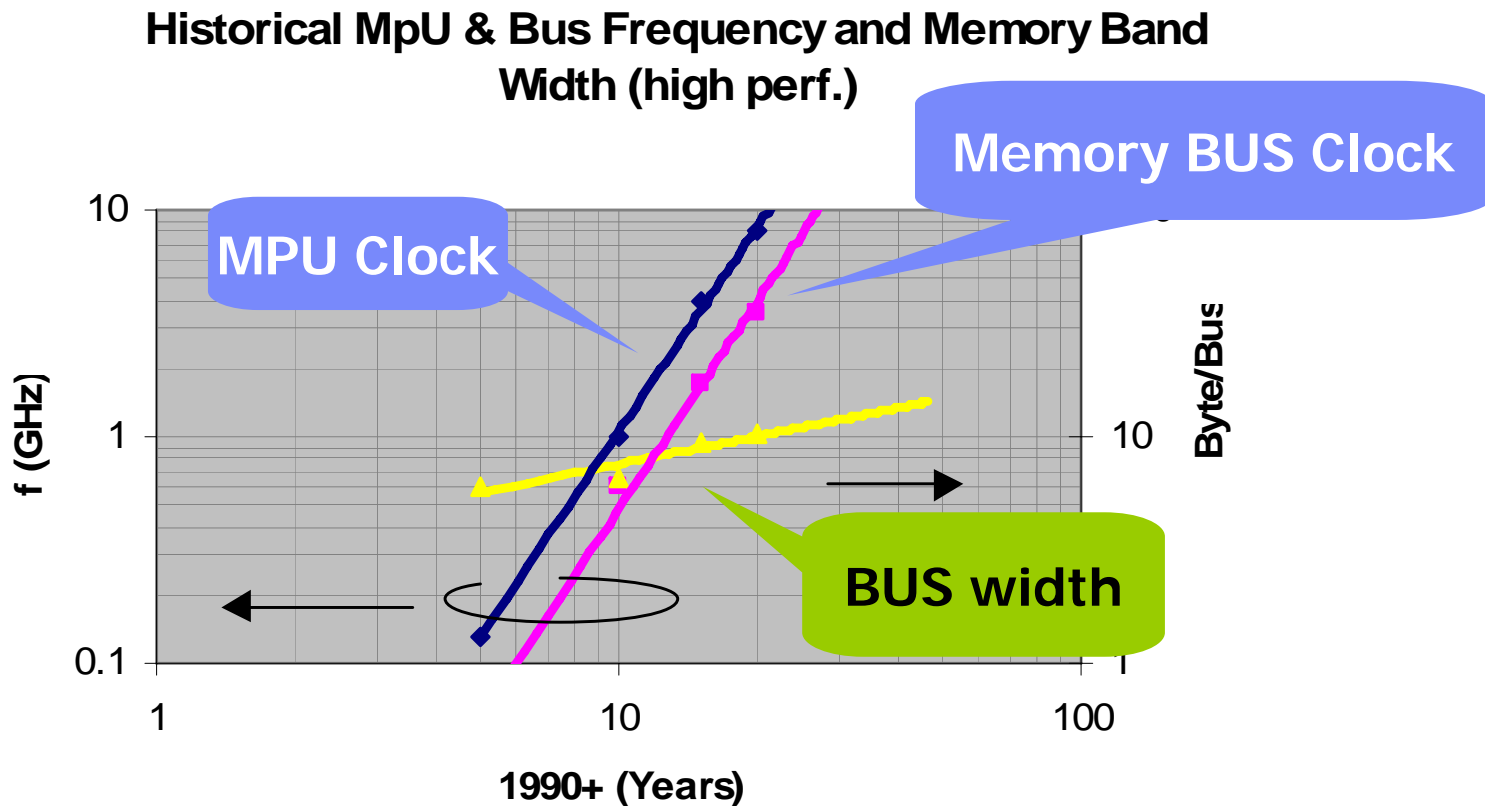
Increasing Cache Size Drives Chip Size

Floorplans source: P. DeMone, "Sizing Up the Super Heavyweights," *Real World Technologies* Report, 9/17/2004



- Growing data sets will increasingly stress cache size
- Multi-core floor planning and SRAM concerns will halt cache size growth to maintain manageable chip size

Frequency Drives Datarate

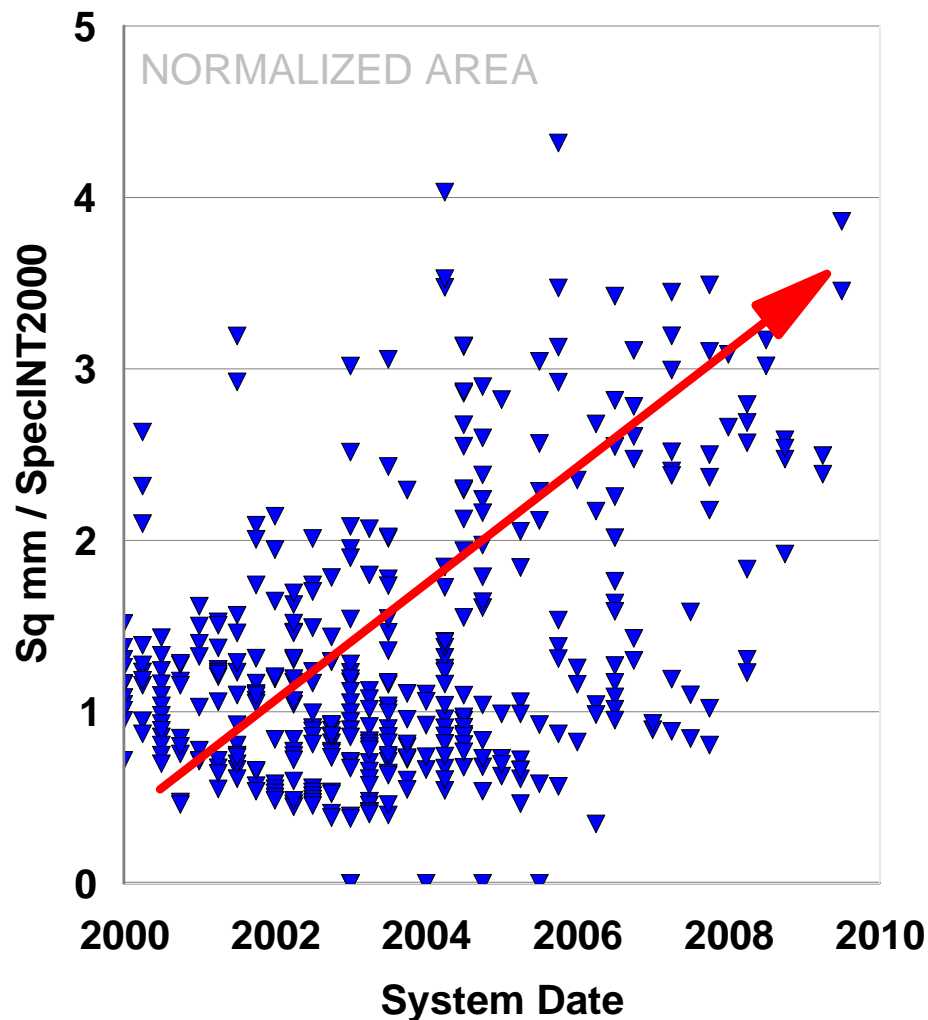


- Data bus frequency follows MPU frequency at a ratio 1:2 roughly doubling every 18 to 24 month
- Data bus band width shows only a moderate increase
 - Data bus transfer rate is basically scaled by bus frequency
- **When clock growth slows, BUS data rate growth will slow too!**

Architecture Net

- Growing the number of cores/chip increases demand for bandwidth
- Transaction retirement rate dependence on data delivery is *increasing*
- Transaction retirement rate dependence on λP performance is *decreasing*

Die Area Increase



- 1) Architecture overhead increasing area of die
- 2) Accessible portion of chip over normalized cycle time is decreasing generation over generation
- 3) Deeper Pipes are decreasing delay per cycle

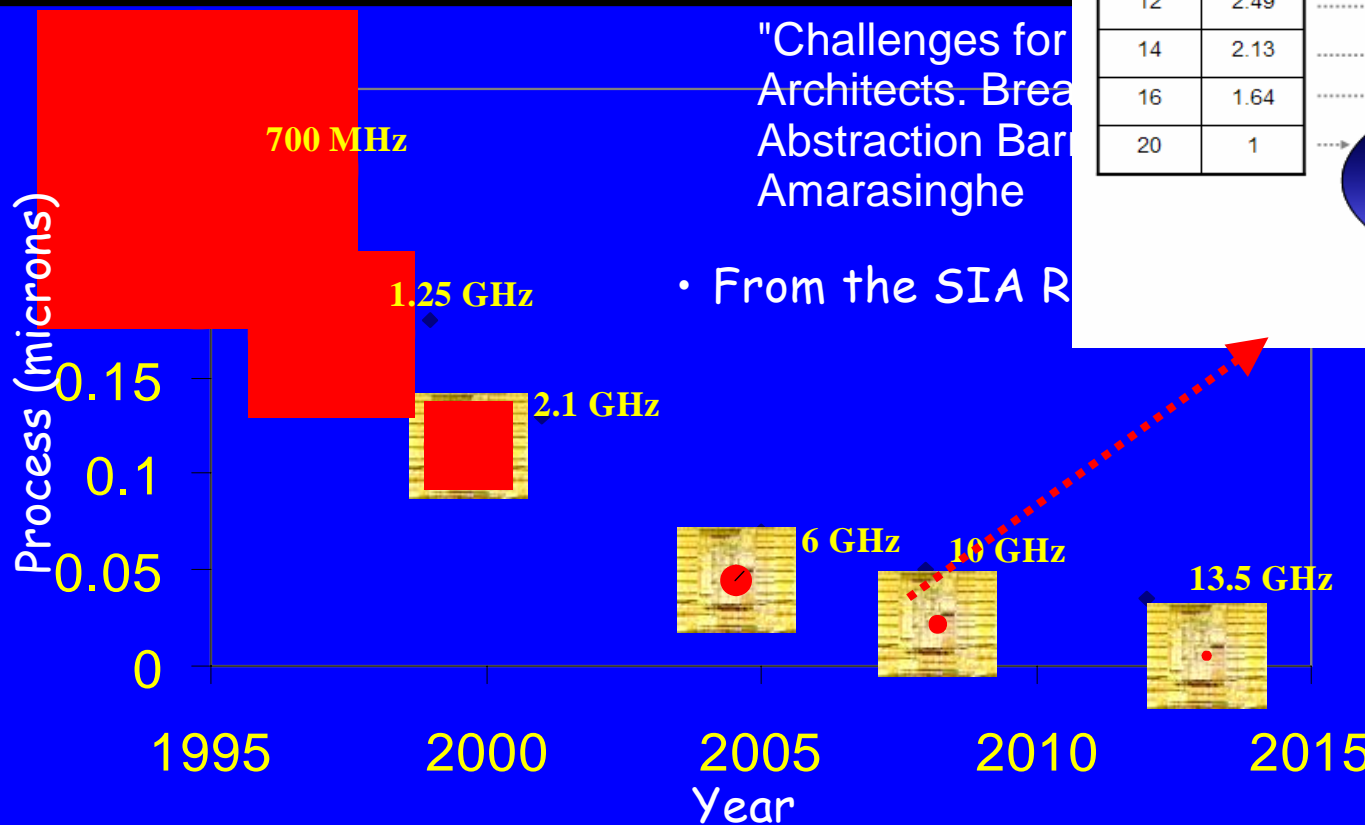
Performance is expensive when left to architects!!

“Span of Control” with Scaling

Lack of wire delay improvement, die-size growth, and shorter relative cycle stage-depth together cause reduction in fan-out capability

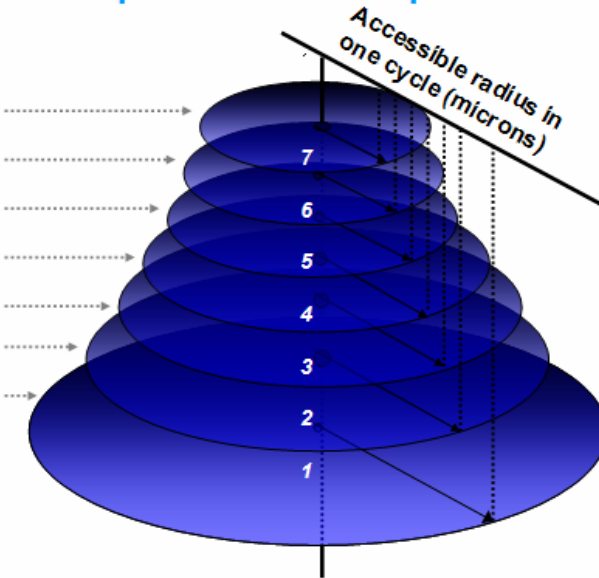
"Challenges for Architects. Break Abstraction Barrier" Amarasinghe

• From the SIA R



No. of stage delays at this level	Span of control Imprvmt (Norm)
8	3.10
9	2.94
10	2.74
12	2.49
14	2.13
16	1.64
20	1

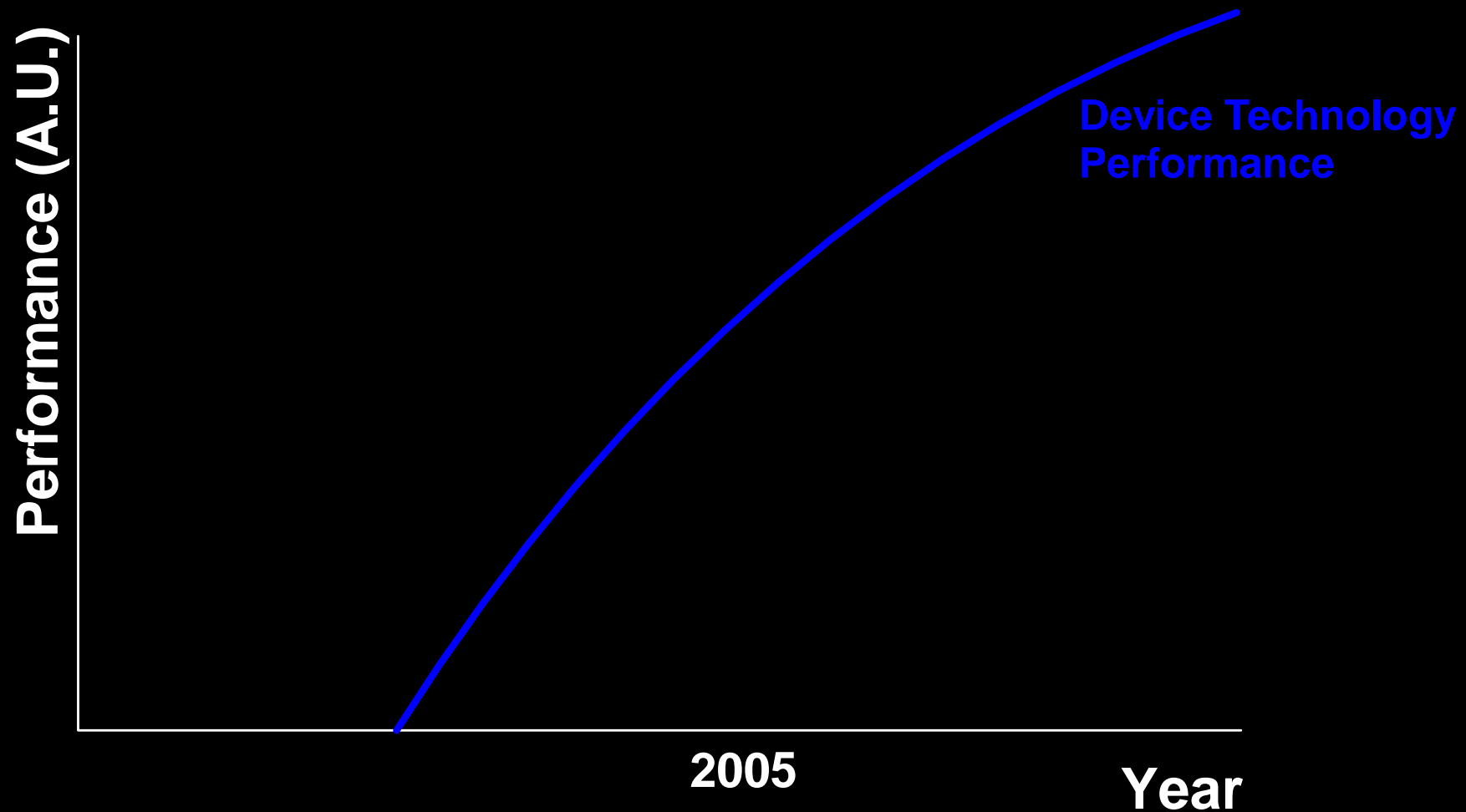
3DI Span of Control Improvement



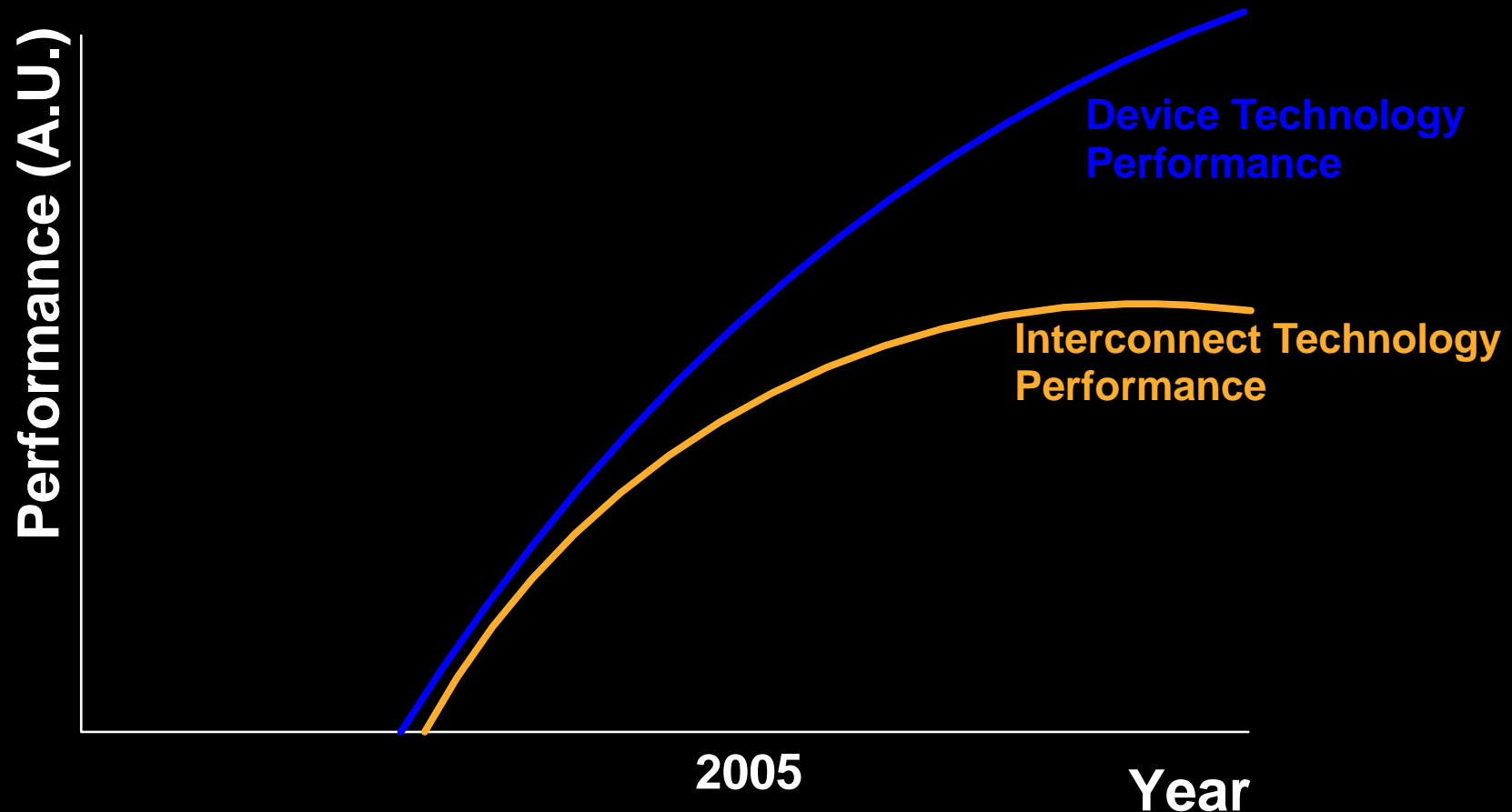
- Perfect Storm: (a)Wire non-scaling; (b) die size growth; (c)Shorter FO4 stages
- Power Cost of Cross-Chip Latency increase

First, a look at a “coincidence”

Device performance (i.e. I/C_G) continues to improve, however at a decreasing rate.....

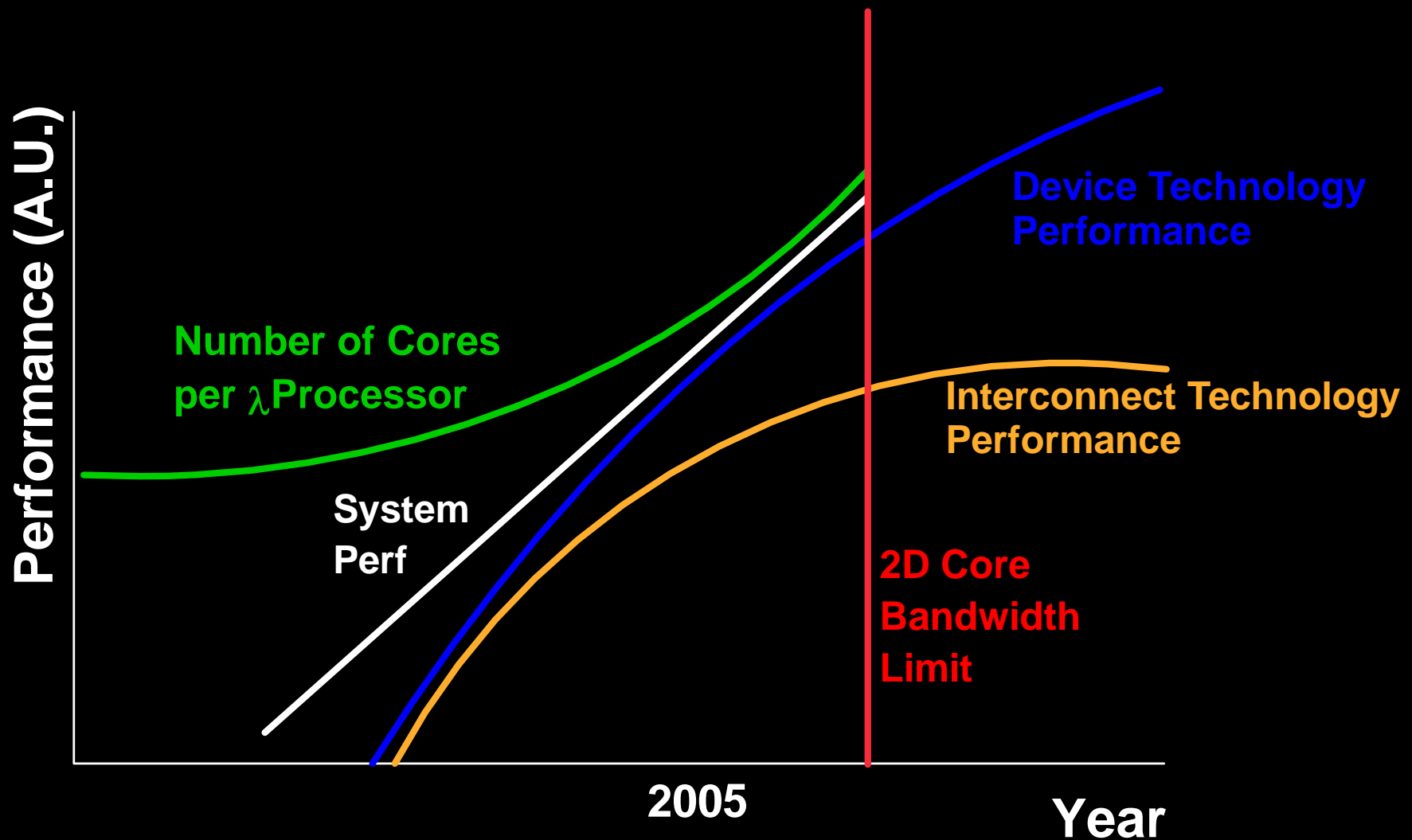


Despite constant infusion of new materials and processes however, interconnect technology performance has at best remained flat.



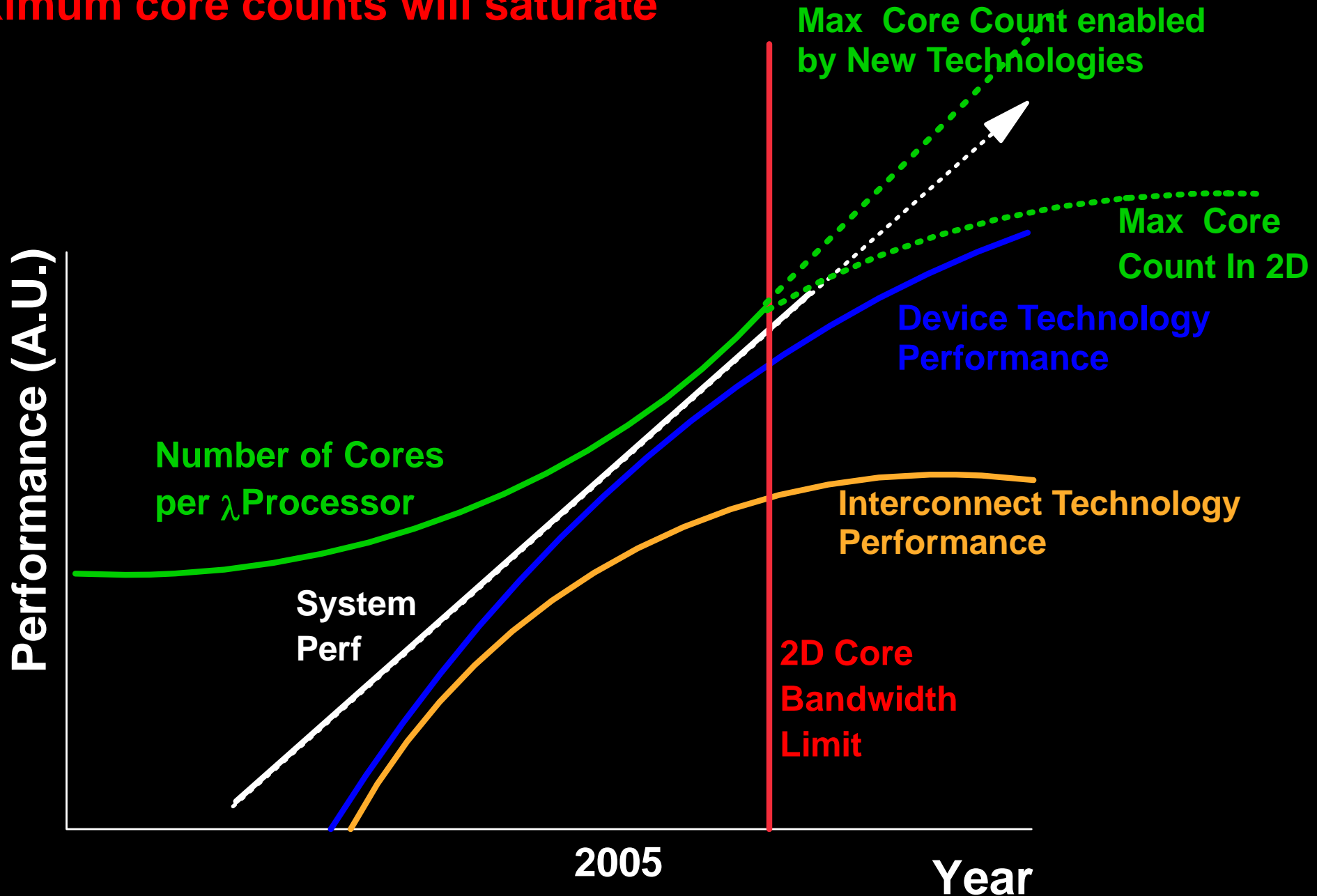
Scaling has increased the divergence between FEOL and BEOL contributions to performance improvement

As effective distances on chip increased due to interconnect, cores/chip has begun to climb. The bandwidth needed to feed these cores will ultimately **limit** number of cores



System Performance improvement is sustained more by the number of cores rather than by the performance of each core

**Without more bandwidth at low latencies,
maximum core counts will saturate**



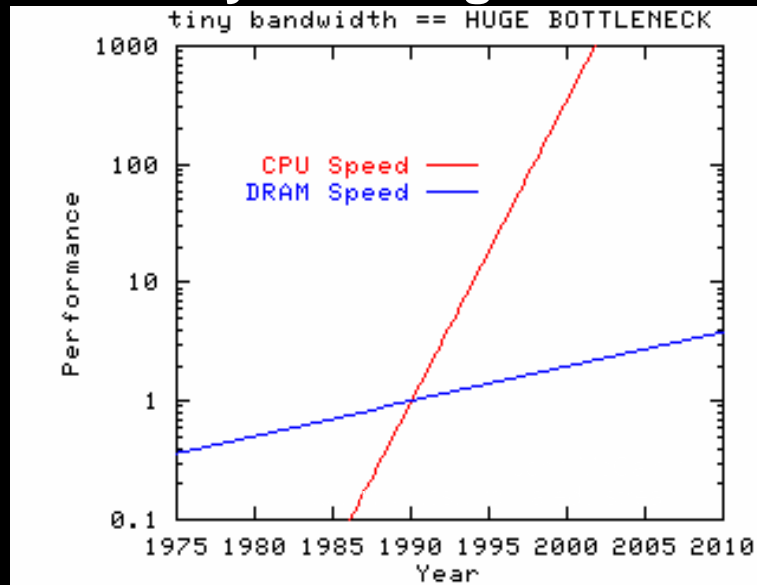
3D extends transfer of performance from the device to the core level

The Memory Wall, Bandwidth, and Latency

Getting over the Memory Wall

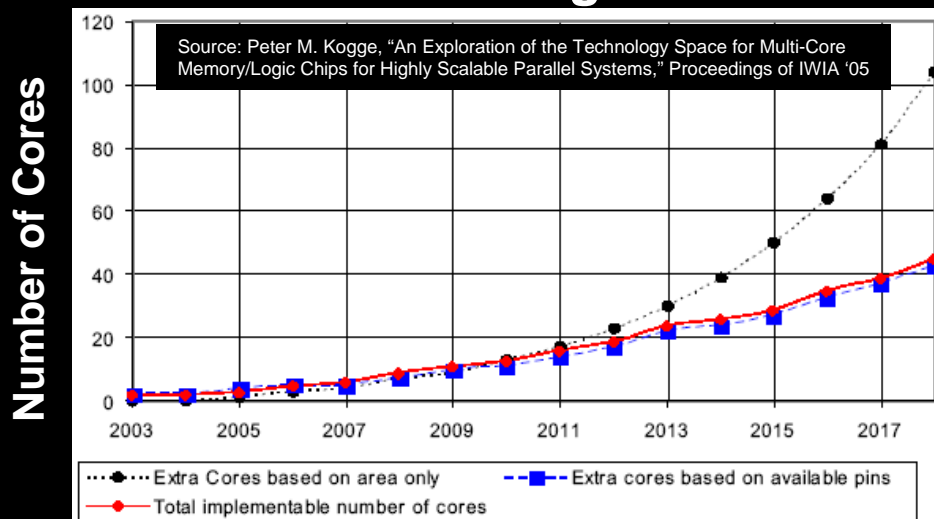
Microprocessor Architectures Fundamental Bus Limits

Latency Challenge



- Processor speed has increased much quicker than memory access
- Result: λP 's data appetite has grown quicker than ability to feed it.
 - What needs higher BW?
 - Multi-cores with limited cache
 - Multi-threading
 - Virtualization

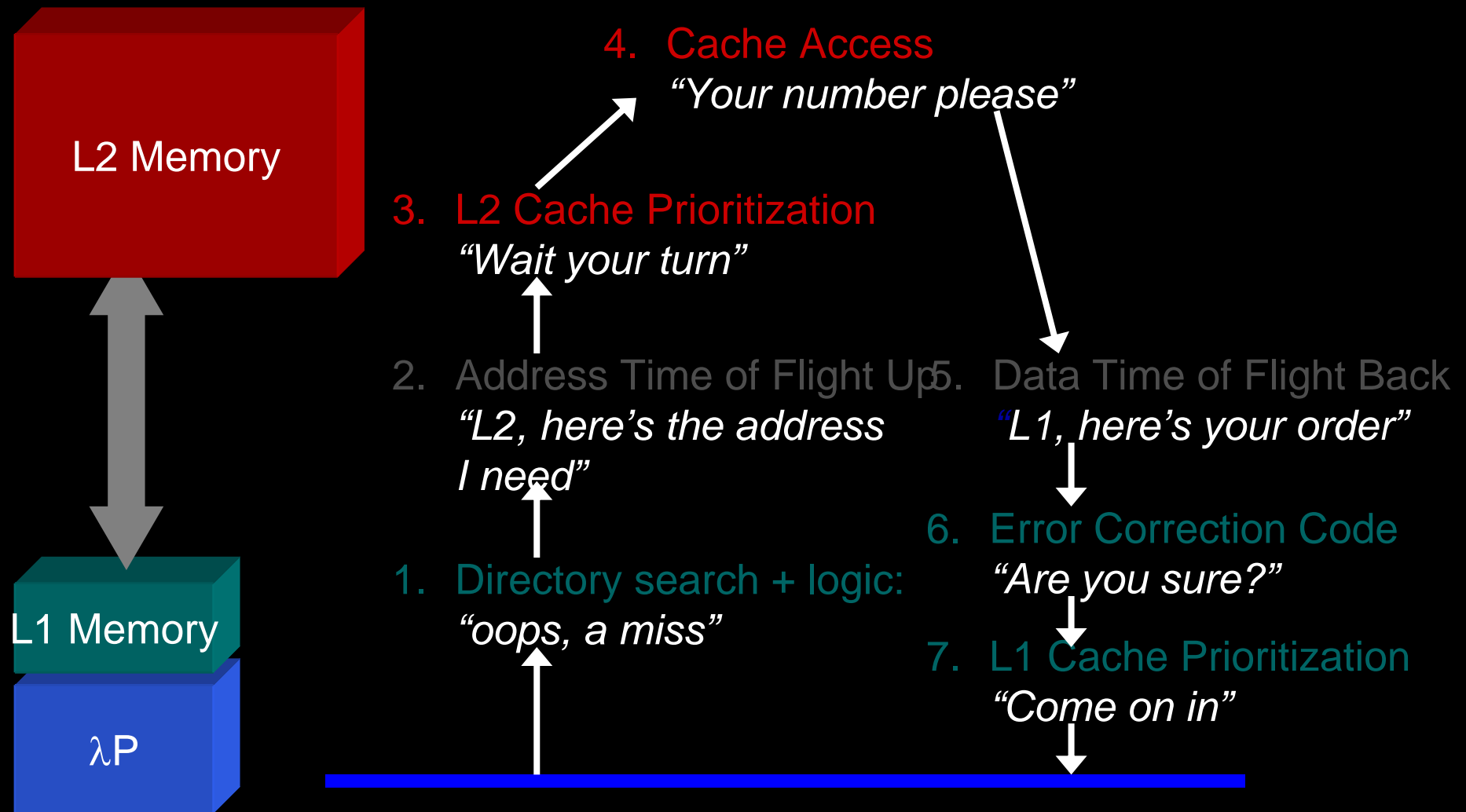
Bandwidth Challenge



- Increasing "cores per chip" addresses memory latency. Core count Limit after 2010 will be from pins used to provide memory bandwidth
 - The "Memory Wall" is back with a vengeance

Architecture

Cache Miss Penalty Calculation

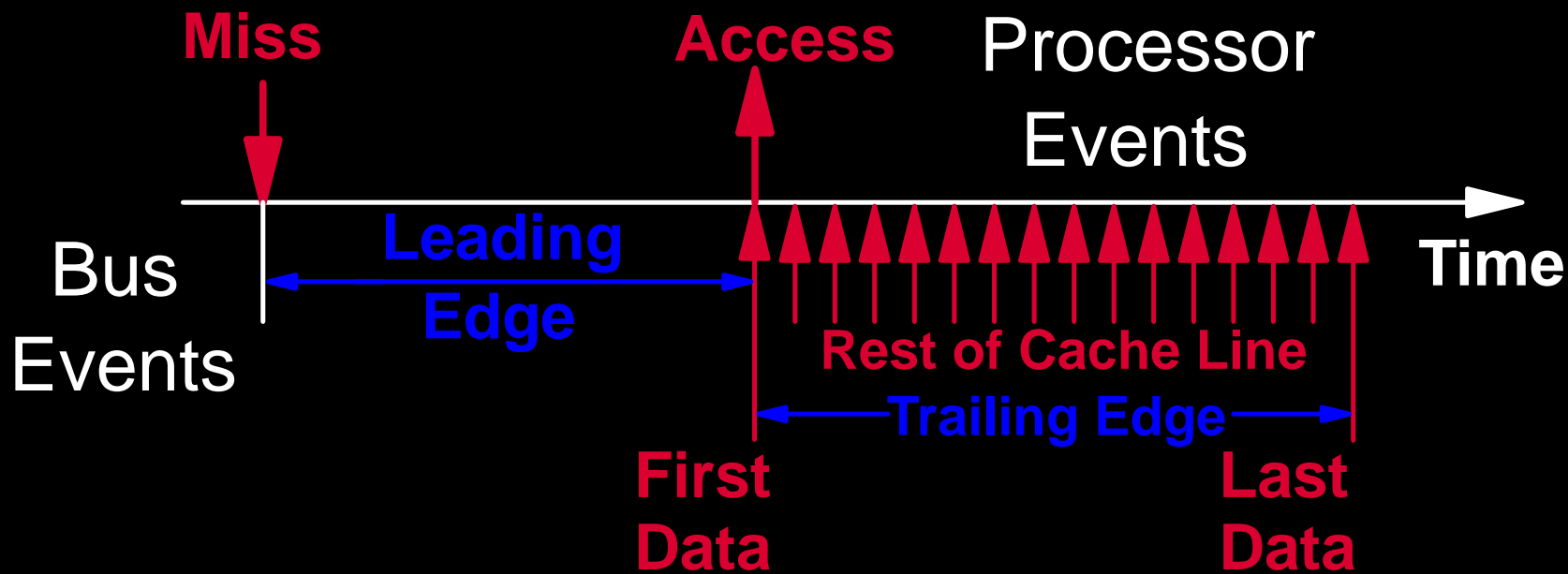


Memory Latency is the delay encountered completing the loop above

Bernstein

What Is Bandwidth Used For?

In a computer, it is mostly for handling cache misses:1

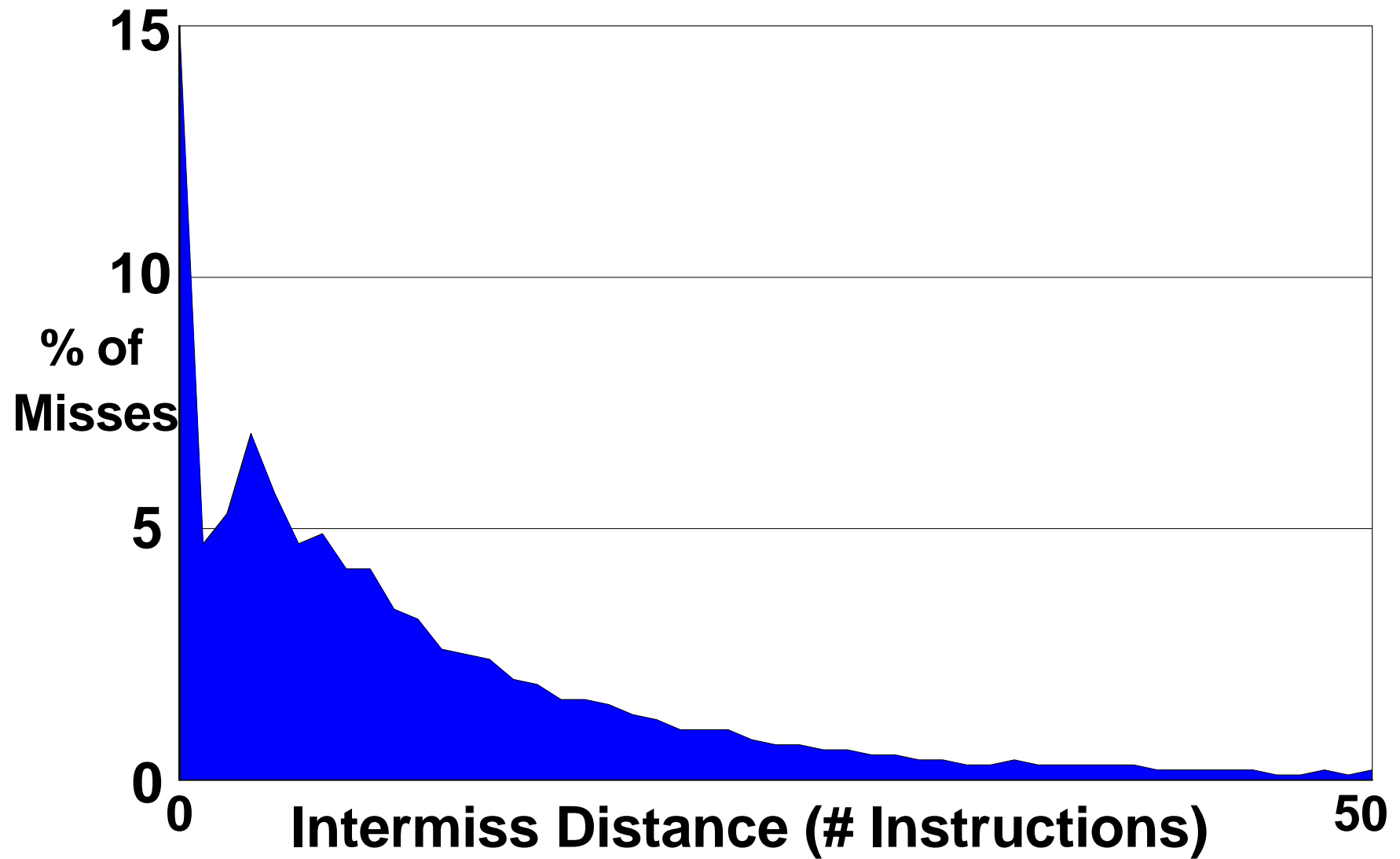


Miss Penalty = Leading Edge + Effects(Trailing Edge)

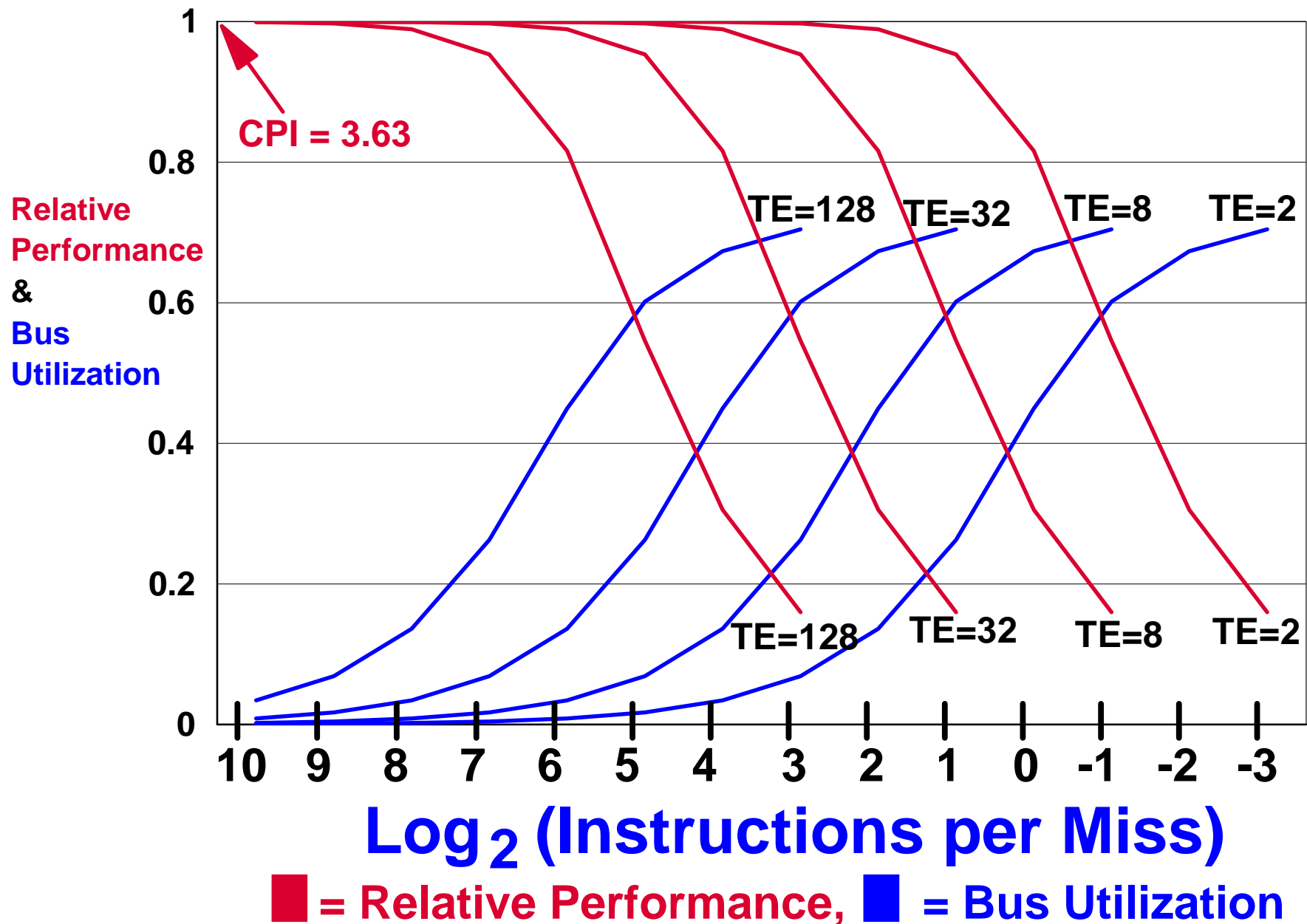
Where

$$\begin{aligned} \text{Trailing Edge Effect} &= (\text{Line Size} / \text{Bus Width}) \times (F_{(\lambda P)} / F_{(\text{Bus})}) \\ \text{Bus Utilization} &= (\text{Trailing Edge} / \text{Intermiss Distance}) \end{aligned}$$

Intermiss Distance Density



Queueing Effects vs. Log Miss Rate



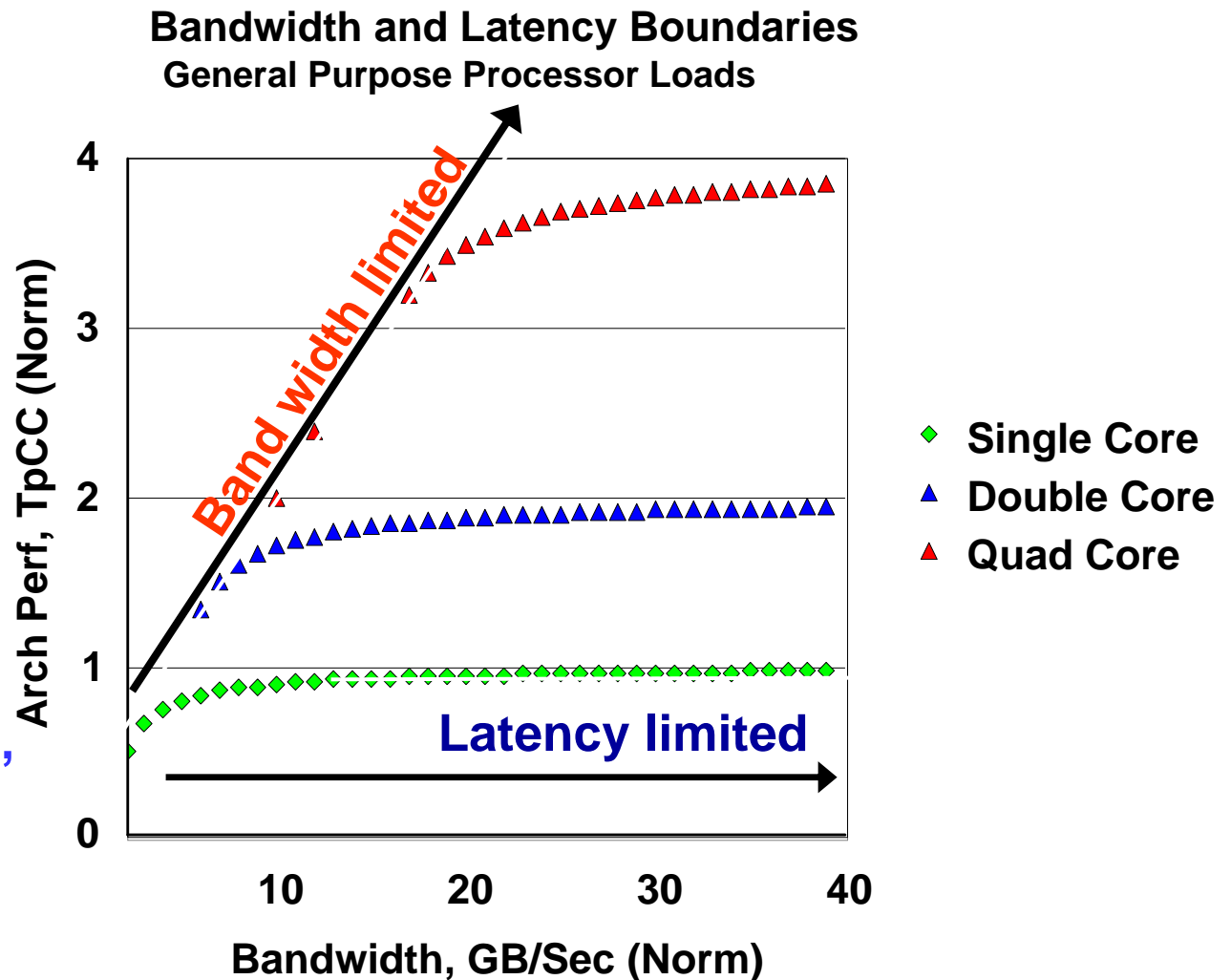
Server Trends are hard on Bandwidth

- **Frequency is no longer increasing**
 - Logic speed scaled faster than memory bus
 - (Processor clocks / Bus clock) consumes bandwidth
- **More speculation multipliers prefetch attempts**
 - Wrong guesses increase miss traffic
- **Reducing line length is limited by directory as cache grows**
 - But doubling line size doubles bus occupancy
- **Cores / die increasing each generation**
 - Multiplies off-chip bus transactions by $N / 2 \cdot \sqrt{2}$
- **More threads per core, and increase in virtualization**
 - Multiplies off-chip bus transactions by N
- **Total number of Processors / SMP increasing**
 - Aggravates queuing throughout the system

3D - Bandwidth and Latency

Processor load trade-off between I/O Bandwidth, Bus Latency.

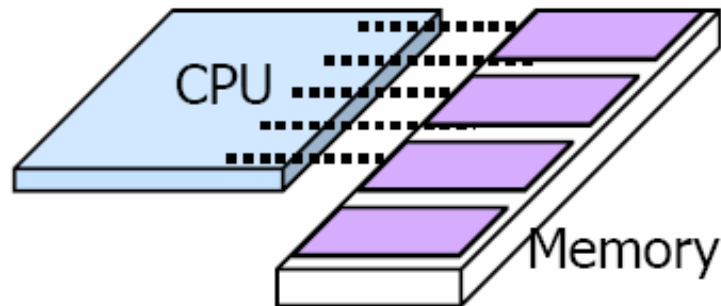
- For generic workloads, uni-processor perf saturates bandwidth benefit, becomes latency-limited.
- As core counts increase, I/O Bandwidth becomes increasingly important



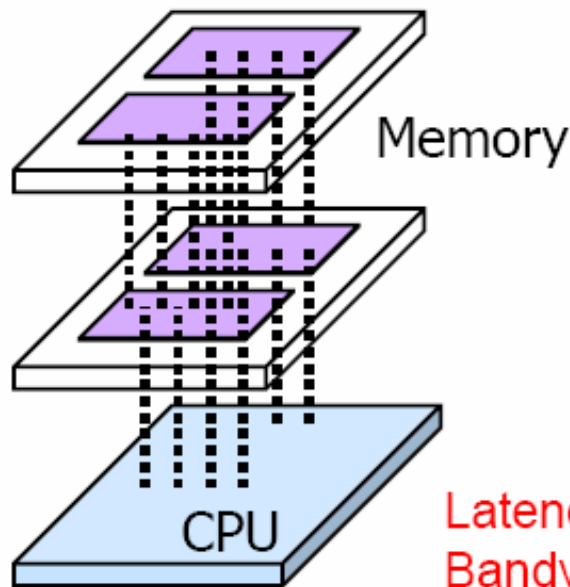
3D opportunity for improving High Perf Compute throughput in sustaining a higher number of cores per chip

3D Solution

Hierarchical Memory Access



- 2-D: Connections on the periphery
- Long global connections
 - CPU to off-chip main memory with latency and misses



- 3-D: Connections across the area
- Connections short + vertical
 - Suitable for high-bandwidth and vector operations
 - No pin cost, large block access of data

Latency: Important for random access (servers, e.g.), single core

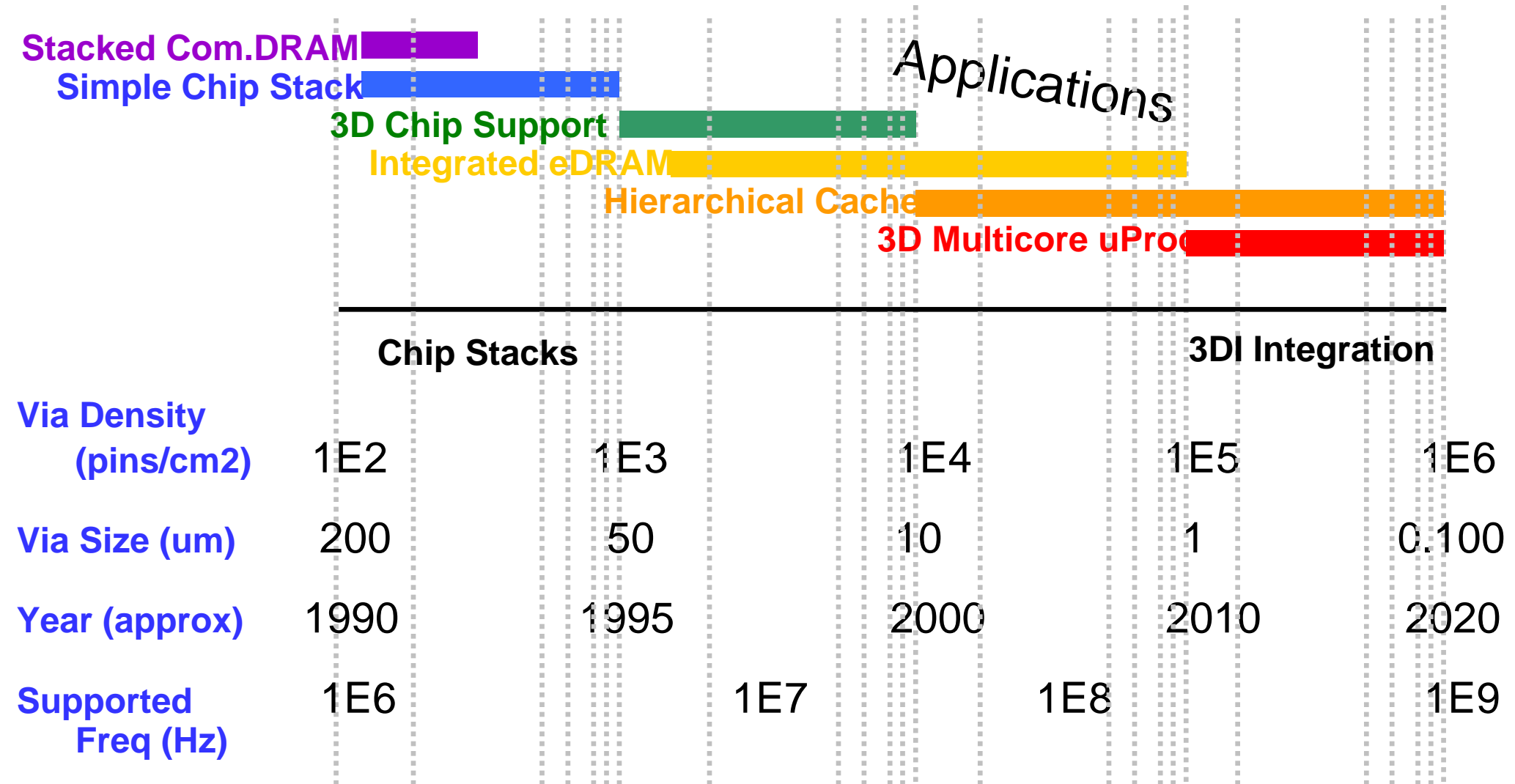
Bandwidth: Multiple cores, multi-threads, graphics

S. Tiwari; "Potential, Characteristics, and Issues of 3D SOI; 3D SOI Opportunities"
Short Course, 2005 International SOI Conference

The Technologies of 3D Integration

(and their challenges)

The 3D Integration Technology Spectrum

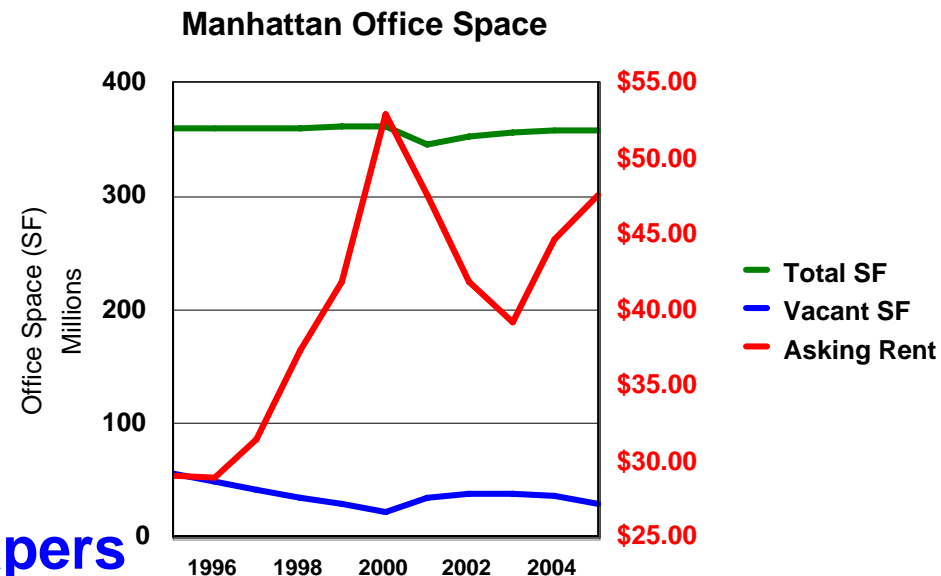
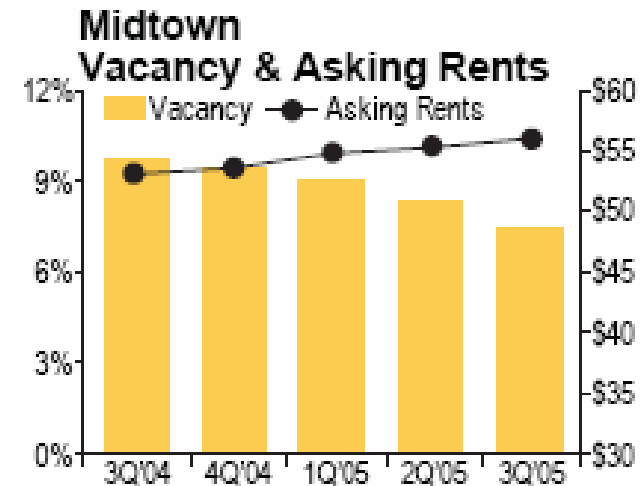


Precedent for 3D Integration:

When Real Estate Becomes Pricey



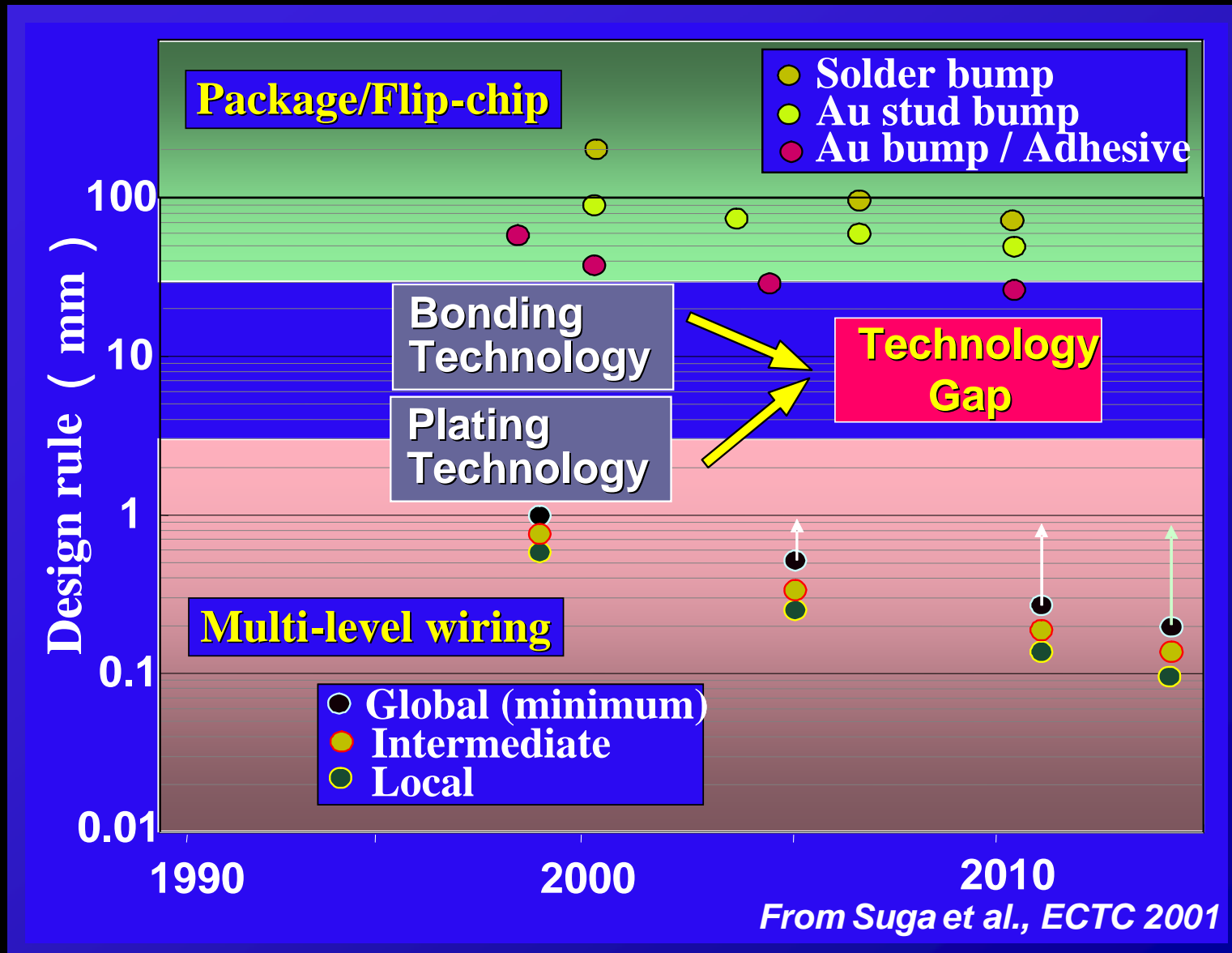
Vertical Integration isn't new!



Data courtesy of Richard Persichetti
Grubb & Ellis, New York, NY

NYC Office Inventory, Rent, and Skyscrapers

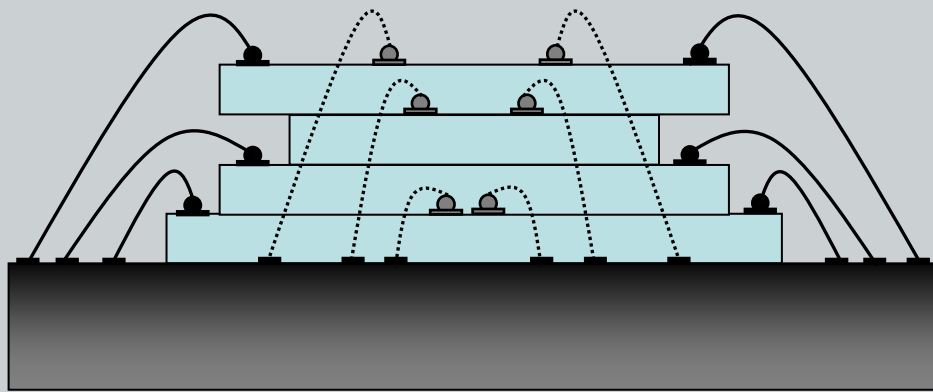
Chip-Package Technology Gap



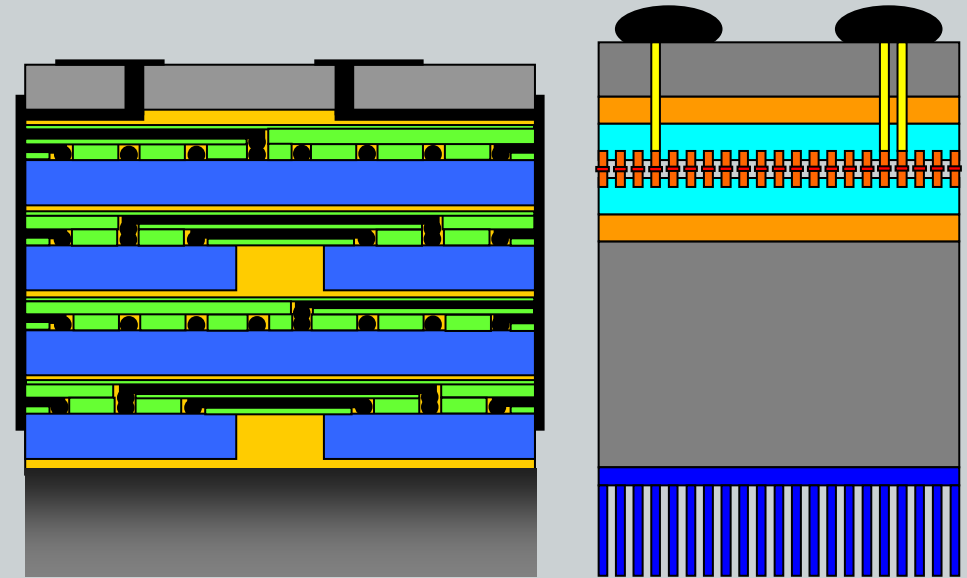
- Technology gap in the design rule between on-chip wiring and packaging interconnects

2. Present Vertical Interconnect Schemes

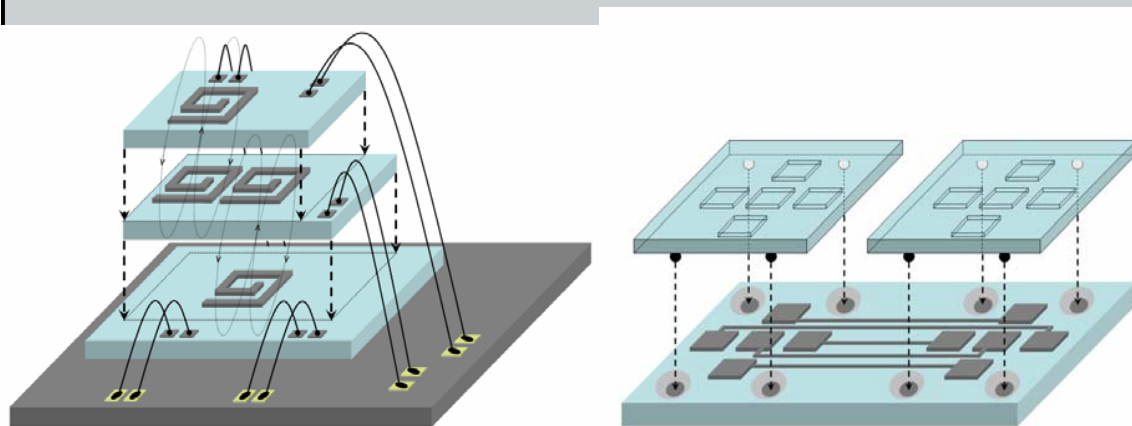
Images used by permission, W.R. Davis, North Carolina State Univ,



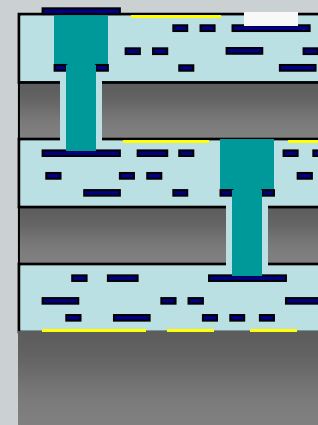
Wire Bonding



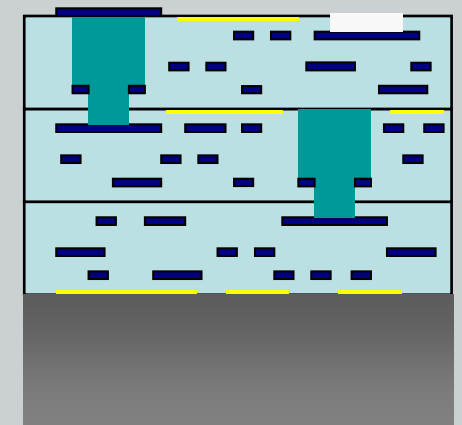
Microbump



Coupled Virtual Connections



(a) Bulk



(b) SOI

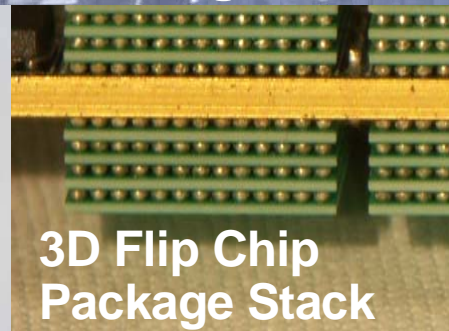
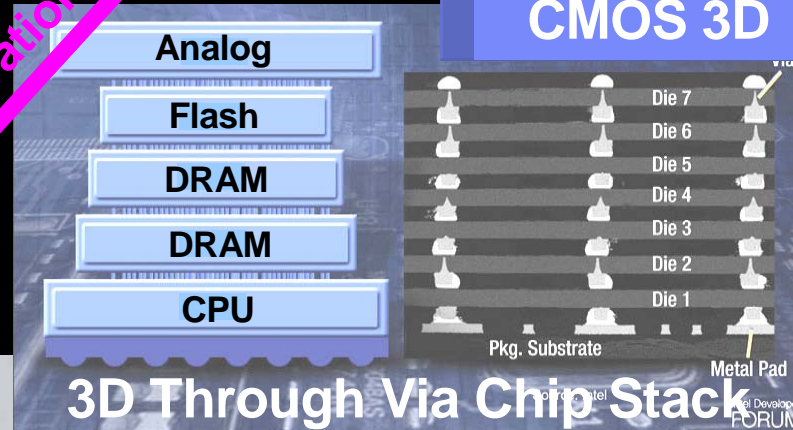
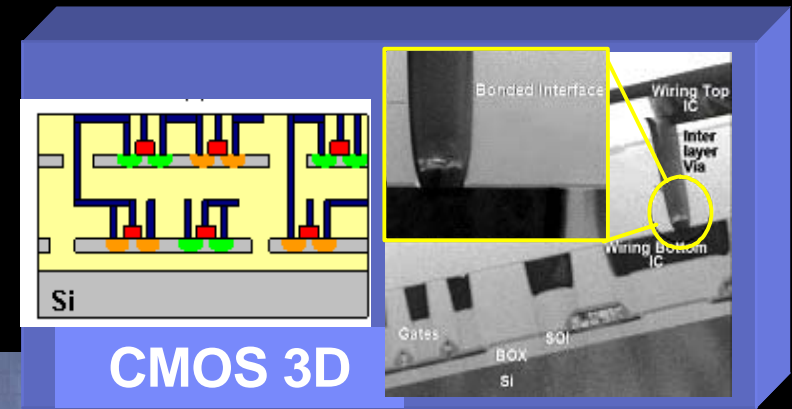
Through-Via

Evolution of 3D Integration

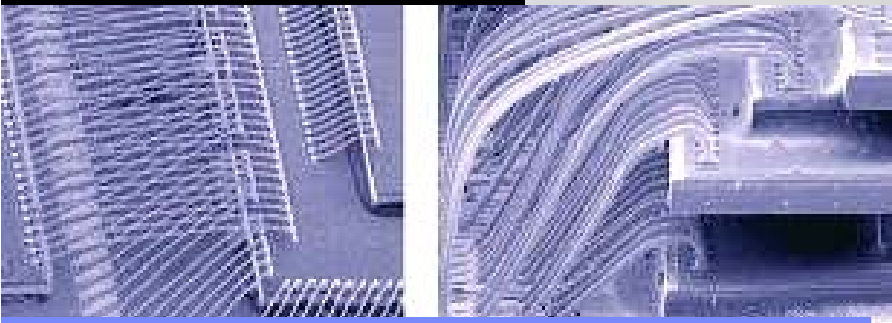
Technology Investment in the Z-Dimension

- 3D Technologies continue the sequence of interconnect advances
- Return balance to device scaling
- Enable new capabilities not available in 2D

Increasing 3D Integration



- 3D Packaging R&D now pervasive in industry, academia
- Through-via technology emerging as predominant path
- 3D has *always* been large volume, but now integrating higher technologies



Wire bonded chip stacked 3D

Key 3DI Processes

Images courtesy of Anna Topol,
IBM T.J. Watson Research Center

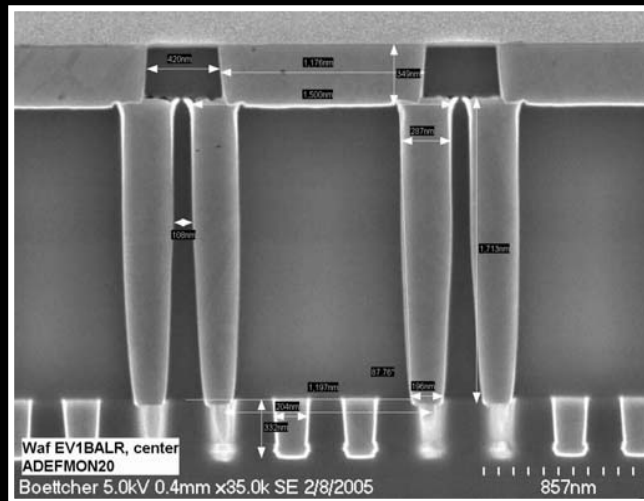
Bonding



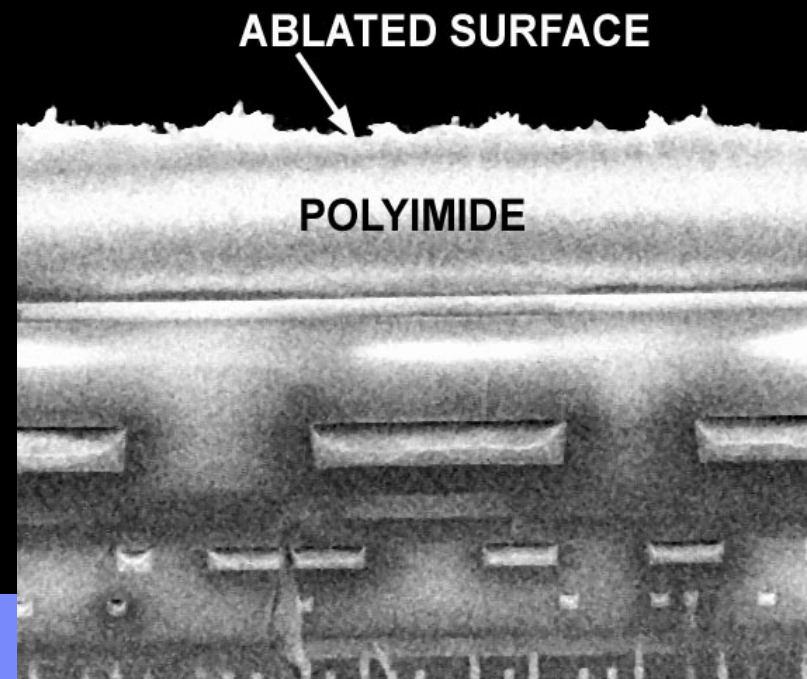
Transfer/Alignment



Electrical Contacting

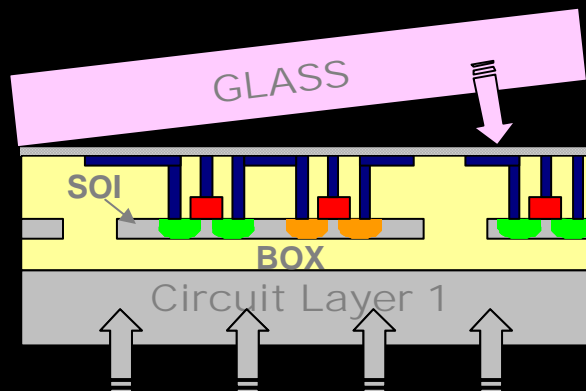


Release Process

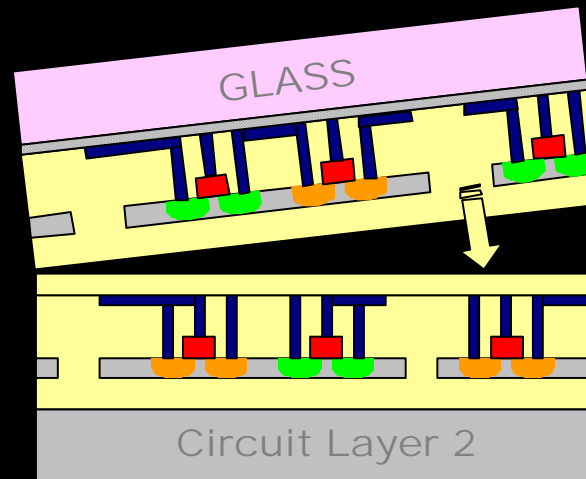


IBM 3D Process: SOI-Based 3DI Layer Transfer

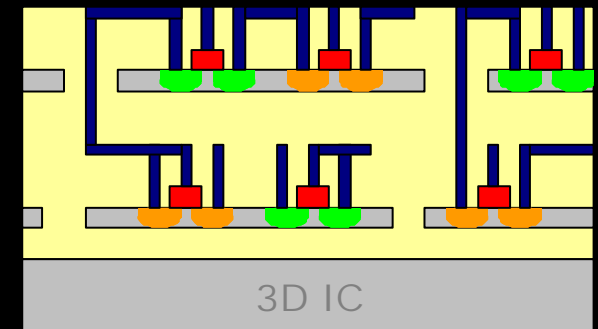
- Device layers stacked using wafer bonding
- Each layer fabricated by conventional processes
- Layers fabricated and tested simultaneously



- Attach circuit to glass handle wafer
- Remove original substrate



- Align & bond top circuit to bottom circuit

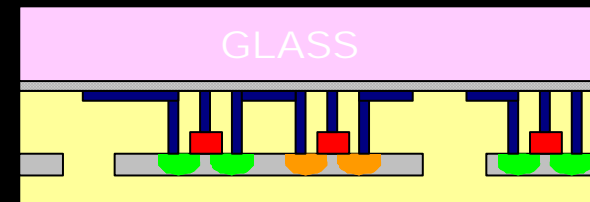
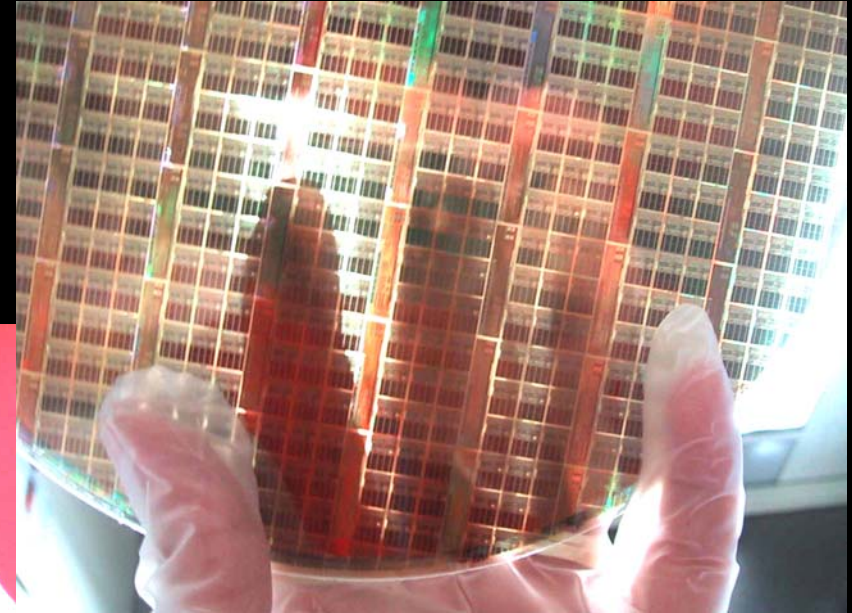
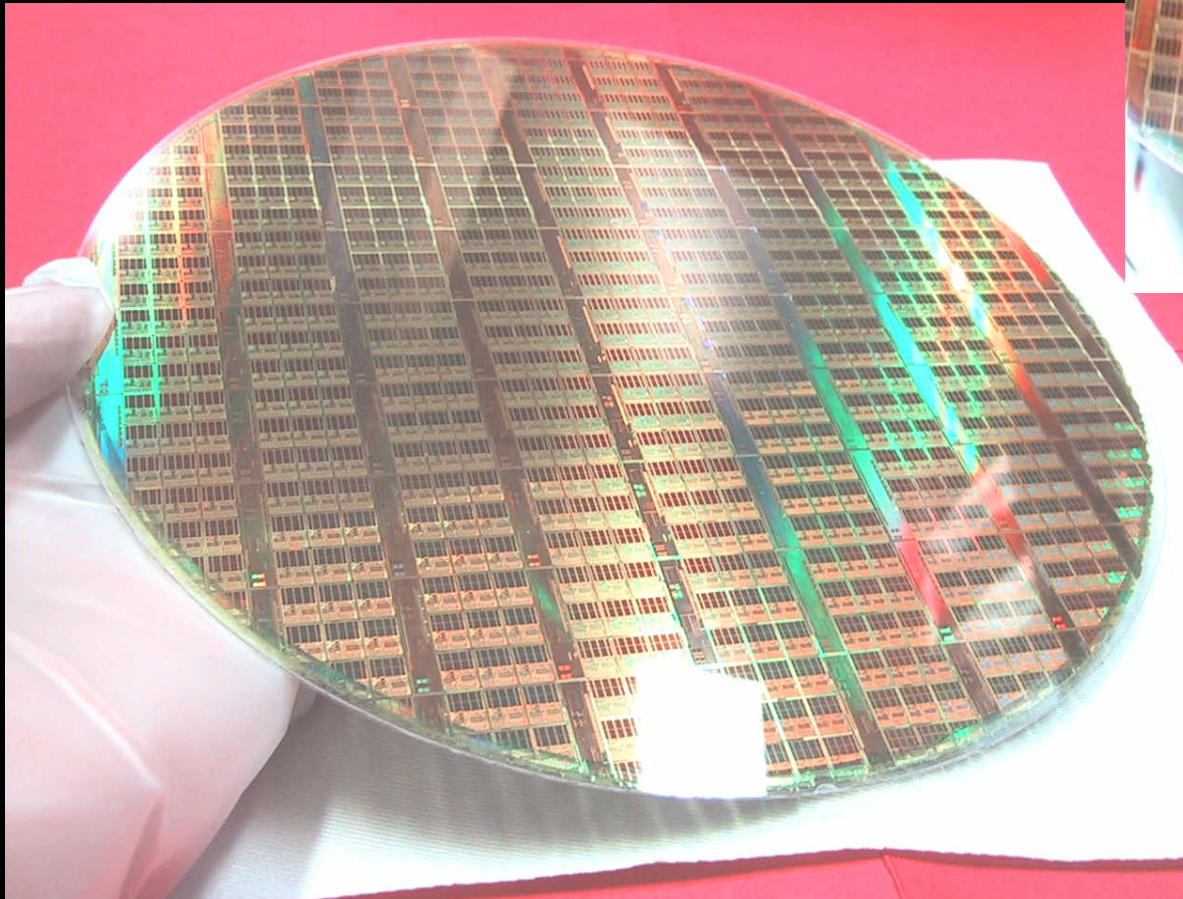


- Remove handle wafer & adhesives
- Form vertical interconnects

Wafer Transfer / Thinning

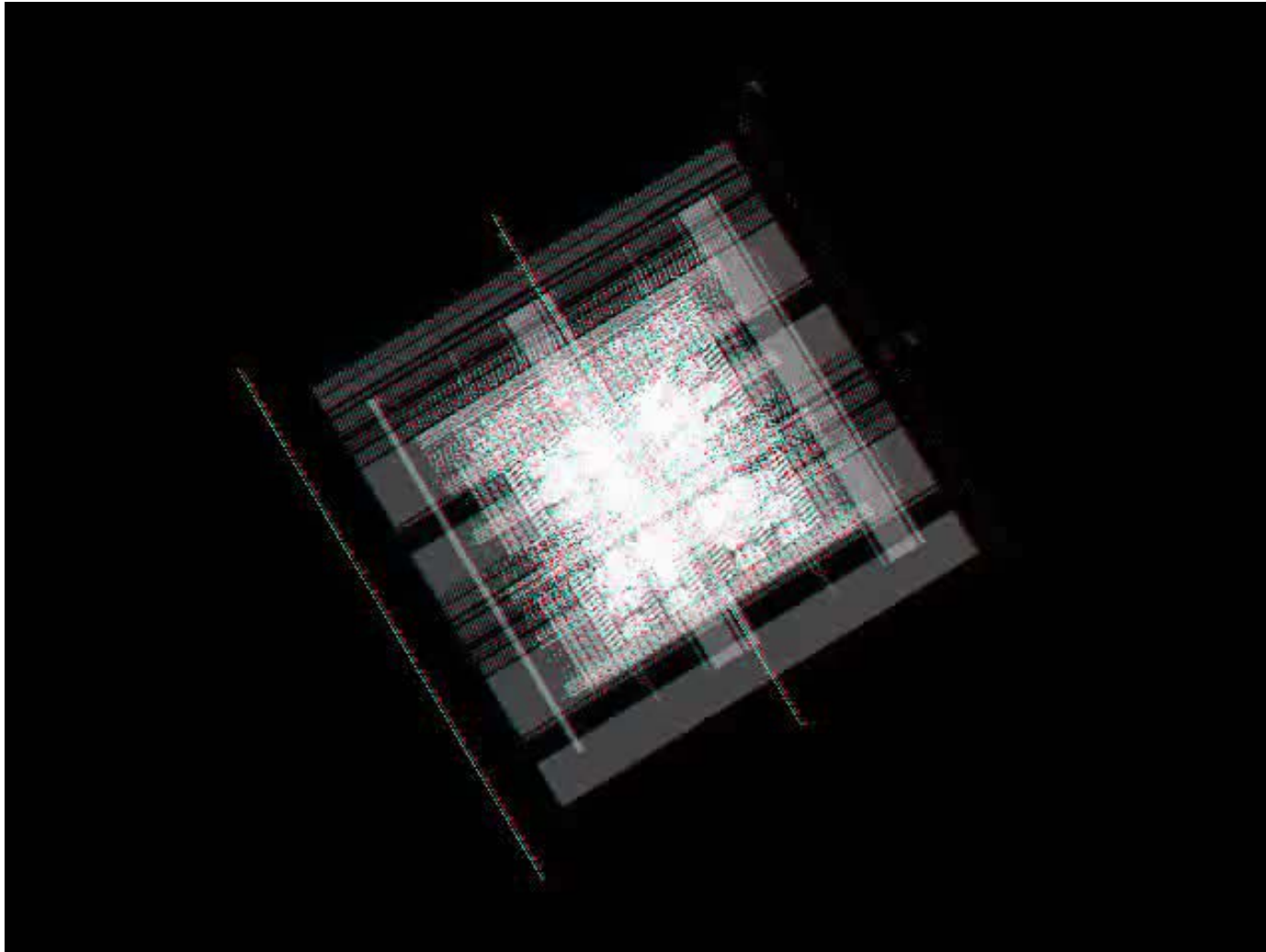
K. Guarini, IEDM, 2002.

Transparent Circuit
200 mm Wafer
130nm SOI Technology



- SOI device layer + back-end metallization transferred onto glass
- Defect-free lamination over 200 mm wafers

3D Fly-Thru Movies of IBM Assembly



3D Challenges

Heat Dissipation and Natural Selection

Why is area vs volume such a big deal?



Power/Energy Issues

- It now takes more energy to move data than to generate it, even just across chip
 - Compute: 50pJ / FLOP / bit
 - Read: 10 pJ / operand from Reg....but
1 nJ / operand from cache
- Worst power nets on chip are data, instruction nets: go from mm(2D) to λ m(3D)

Slice: Temperature [$^{\circ}\text{C}$] Arrow: Total heat flux [W/m^2] Streamline: Total heat flux [W/m^2]

Max: 100

100

90

80

70

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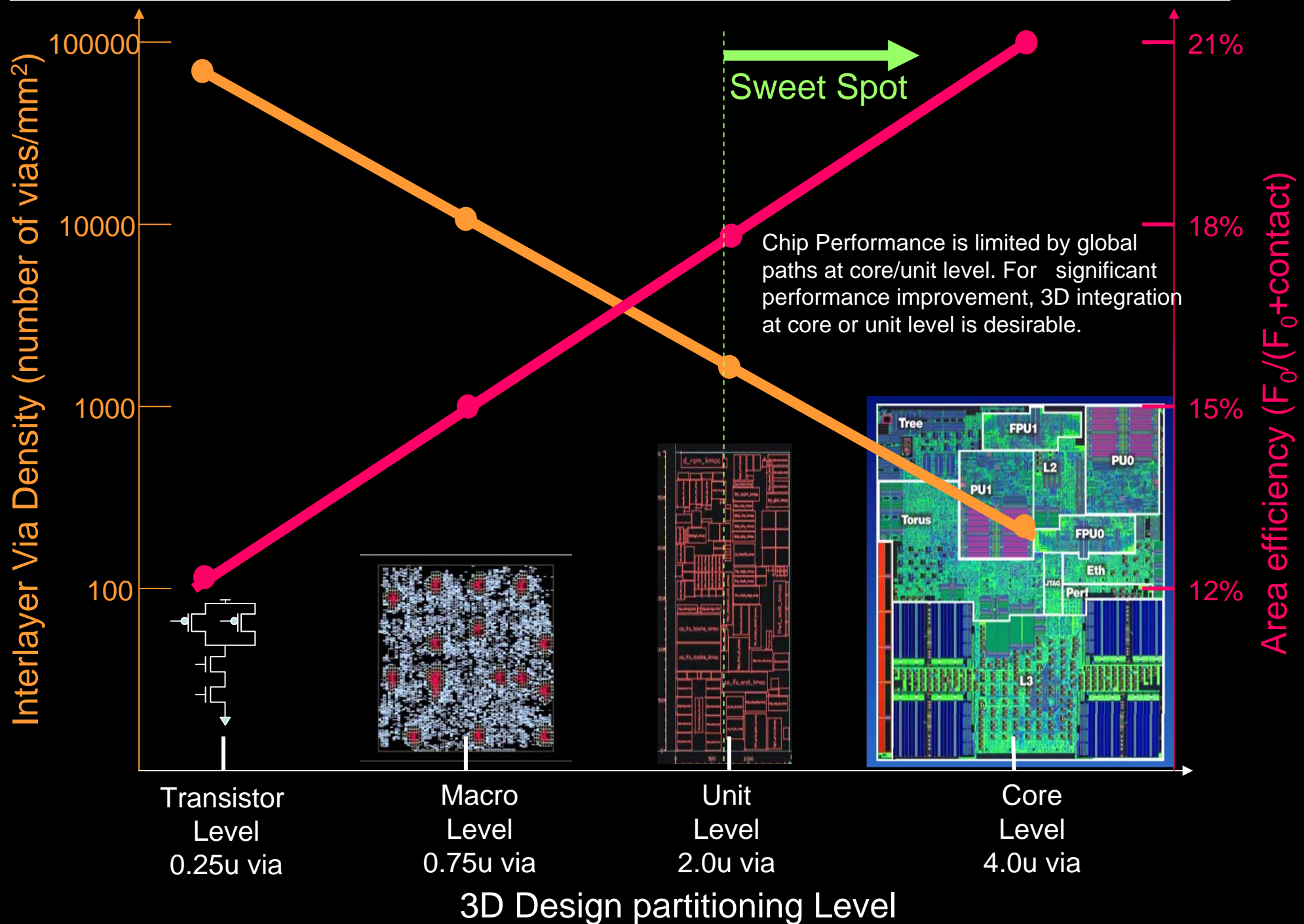
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C. EDA and 3D Integration Trends



7. Summary

- λP architecture tricks to avoid atomistic, QM scaling boundaries overwhelm present interconnects
- Integration into Z-plane again postpones interconnect-related limitations to extending classic scaling.
- Transaction retirement rate dependence on data delivery is *increasing*: dependence on λP performance and CMOS device speed is *decreasing*
- 3D Integration improves storage density & access to that storage
- 3D Integration will enable previously unattainable capabilities characterized by realtime access to massive amounts of storage.

Human Scaling

Tomorrow's microprocessors will be improved with capabilities developed using today's machines

Tomorrow's engineers will design microprocessors with insights they learn from today's engineers and professors.

Engineers/professors today insure a bright tomorrow by transferring **ideas** as well as **technologies** to the next generation.

